

Low Voltage Input LDO Voltage Regulator with Soft-Start Function

■ GENERAL DESCRIPTION

The XC6601 series is a low voltage input CMOS LDO regulator which provides highly accurate ($\pm 20\text{mV}$) outputs and can supply current efficiently due to its ultra low on-resistance even at low output voltages. The series is ideally suited to the applications which require very low dropout voltage operation and consists of a voltage reference, an error amplifier, a driver transistor, a current limiter, a fold back circuit, a thermal shutdown (TSD) circuit, an under voltage lock out (UVLO) circuit, soft-start circuit and a phase compensation circuit.

Output voltage is selectable in 0.05V increments within a range of 0.7V to 1.8V using laser trimming technology and ceramic capacitors can be used for the output stabilization capacitor (C_L).

The over current protection circuit (the current limiter and the fold back circuit) as well as the thermal shutdown circuit (the TSD circuit) are built-in. These two protection circuits will operate when either the output current reaches the current limit level or the junction temperature reaches the temperature limit level.

With the built-in UVLO function, the regulator output is forced OFF when the voltage level at the VBIAS pin or the VIN pin falls below the UVLO voltage level. With the soft-start function, the inrush current from VIN to VOUT for charging C_L at start-up can be reduced and makes the VIN stable.

The CE function enables the output to be turned off and the series to be put in stand-by mode resulting in greatly reduced power consumption. At the time of entering the stand-by mode, the series enables the electric charge at the output capacitor (C_L) to be discharged via the internal auto-discharge switch which is located between the VOUT pin and the VSS pin. As a result the VOUT pin quickly returns to the VSS level.

■ APPLICATIONS

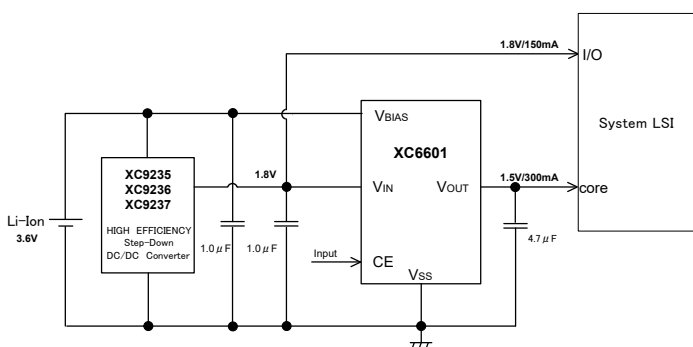
- Smart phones / Mobile phones
- Portable game consoles
- Digital still cameras / Camcorders
- Digital audio equipment
- Mobile devices / terminals

■ FEATURES

| | |
|-----------------------------|---|
| Maximum Output Current | : 400mA (Limit:550mA TYP.) |
| Dropout Voltage | : 38mV@IOUT=100mA (TYP.) (at VBIAS - VOUT=2.4V) |
| Bias Voltage Range | : 2.5V ~ 6.0V (VBIAS - VOUT \geq 1.2V) |
| Input Voltage Range | : 1.0V ~ 3.0V (VIN \leq VBIAS) |
| Output Voltage Range | : 0.7V ~ 1.8V (0.05V increments) |
| Output Voltage Accuracy | : $\pm 20\text{mV}$ |
| Power Consumption | : IBIAS=25 μA , IIN=1.0 μA (TYP.) IBIAS=0.01 μA , IIN=0.01 μA (TYP.) |
| UVLO | : VBIAS=2.0V, VIN=0.4V (TYP.) |
| TSD (Detect/Release) | : 150°C/125°C (TYP.) |
| Soft-Start Time | : 240 μs @ VOUT=1.2V (TYP.) |
| Operating Temperature Range | : -40°C ~ 85°C |
| Function | : CL High Speed Auto-Discharge |
| Low ESR Capacitor | : Ceramic Capacitor Compatible |
| Packages | : USP-6C, SOT-25, SOT-89-5 |
| Environmentally Friendly | : EU RoHS Compliant, Pb Free |

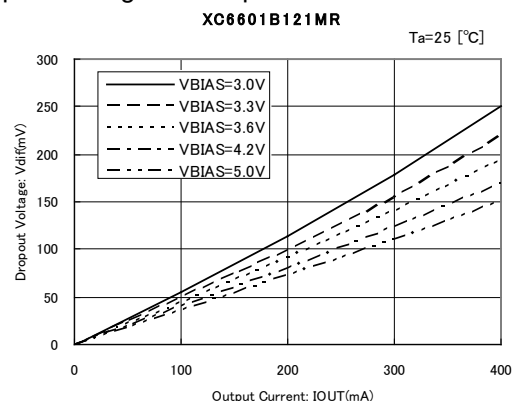
■ TYPICAL APPLICATION CIRCUIT

- VBIAS = 3.6V, VIN = 1.8V, VOUT = 1.5V



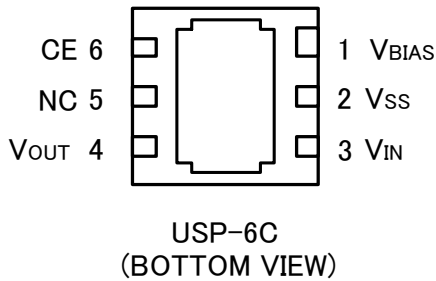
■ TYPICAL PERFORMANCE CHARACTERISTICS

- Dropout Voltage vs. Output Current



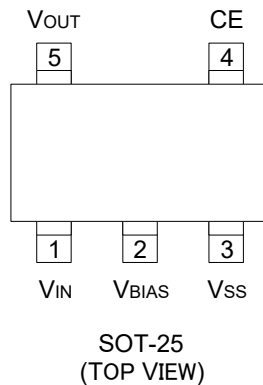
PIN CONFIGURATION

● USP-6C

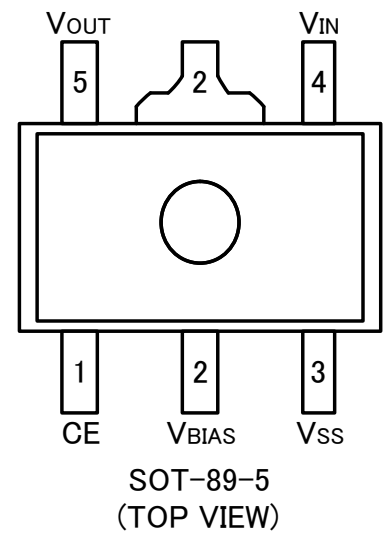


*The heat dissipation pad of the USP-6C package is recommended to solder as the recommended mount pattern and metal mask pattern for mounting strength. This pad should be electrically opened or connected to the VBIAS (No.1) pin.

● SOT-25



● SOT-89-5



PIN ASSIGNMENT

| PIN NUMBER | | | PIN NAME | FUNCTION |
|------------|--------|----------|----------|-------------------------|
| USP-6C | SOT-25 | SOT-89-5 | | |
| 1 | 2 | 2 | VBIAS | Power Supply Input |
| 3 | 1 | 4 | VIN | Driver Transistor Input |
| 4 | 5 | 5 | VOUT | Output |
| 2 | 3 | 3 | VSS | Ground |
| 6 | 4 | 1 | CE | ON/OFF Control |

PRODUCT CLASSIFICATION

● Ordering Information

XC6601①②③④⑤⑥-⑦^(*) : CE High Active, Soft-Start Function Built-in, CL Auto Discharge Function

| MARK | DESCRIPTION | SYMBOL | DESCRIPTION |
|------|-------------------------------------|---------|---|
| ① | Type of Regulators | A | Pull-Down Resistor Built-in |
| | | B | No Pull-Down Resistor Built-in |
| ②③ | Output Voltage | 07 ~ 18 | e.g.) VOUT(T)=1.2V⇒②=1,③=2 |
| ④ | Output Voltage Type | 1 | 0.1V increments e.g.) 1.2V⇒②=1,③=2,④=1 |
| | | B | 0.05V increments e.g.) 1.25V⇒②=1,③=2,④=B |
| ⑤⑥-⑦ | Packages Taping Type ^(*) | MR-G | SOT-25 (3,000pcs/Reel) |
| | | ER-G | USP-6C (3,000pcs/Reel) |
| | | PR-G | SOT-89-5 (1,000pcs/Reel) |

^(*) The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully EU RoHS compliant.

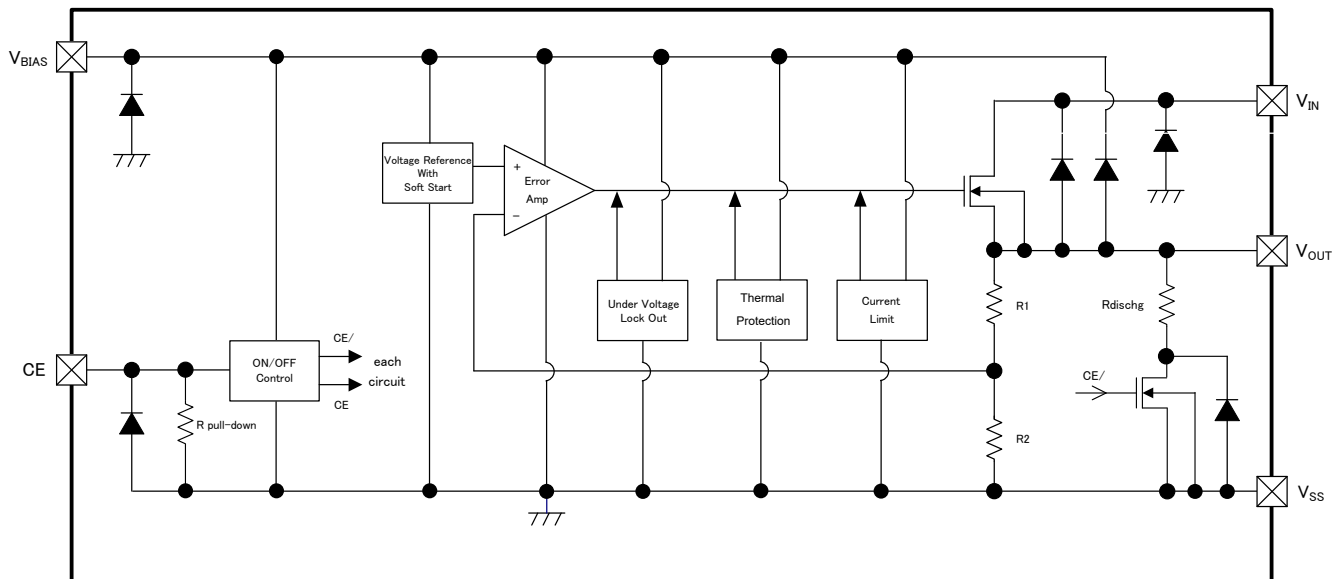
⁽²⁾ The device orientation is fixed in its embossed tape pocket.

For reverse orientation, please contact your local Torex sales office or representative.

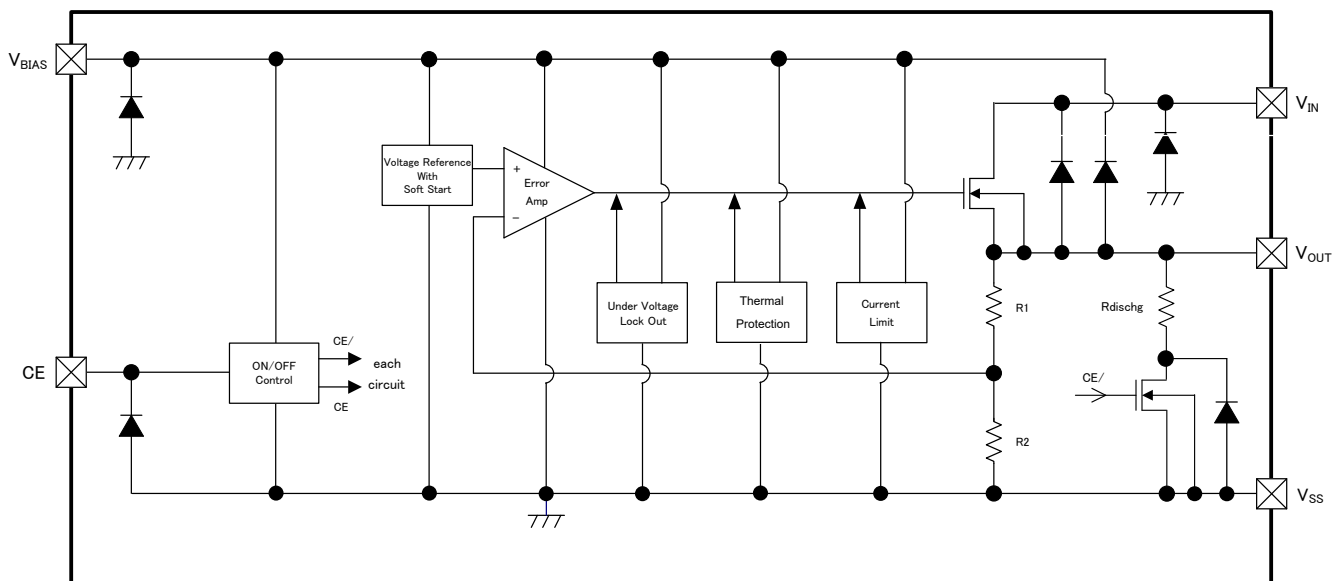
(Standard orientation: ⑤R-⑦, Reverse orientation: ⑤L-⑦)

■ BLOCK DIAGRAMS

(1) XC6601A Series



(2) XC6601B Series



*Diodes inside the circuit are an ESD protection diode and a parasitic diode.

■ MAXIMUM ABSOLUTE RATINGS

Ta=25 °C

| PARAMETER | | SYMBOL | RATINGS | UNITS |
|-----------------------------|----------|------------------|---|-------|
| Bias Voltage | | VBIAS | V _{SS} - 0.3 ~ 7.0 | V |
| Input Voltage | | V _{IN} | V _{SS} - 0.3 ~ 7.0 | V |
| Output Current | | I _{OUT} | 700 ^{(*)1} | mA |
| Output Voltage | | V _{OUT} | V _{SS} - 0.3 ~ V _{BIAS} + 0.3 | V |
| | | | V _{SS} - 0.3 ~ V _{IN} + 0.3 | |
| CE Input Voltage | | V _{CE} | V _{SS} - 0.3 ~ 7.0 | V |
| Power Dissipation | USP-6C | Pd | 100 | mW |
| | | | 1000 (40mm x 40mm Standard board) ^{(*)2} | |
| | | | 1250 (JESD51-7 Board) ^{(*)2} | |
| | SOT-25 | | 250 | |
| | | | 600 (40mm x 40mm Standard board) ^{(*)2} | |
| | SOT-89-5 | | 760 (JESD51-7 Board) ^{(*)2} | |
| | | | 500 | |
| | | | 1300 (40mm x 40mm Standard board) ^{(*)2} | |
| Operating Temperature Range | | Topr | -40 ~ 85 | °C |
| Storage Temperature Range | | Tstg | -55 ~ 125 | °C |

^{(*)1} I_{OUT}=Less than Pd / (V_{IN}-V_{OUT})

^{(*)2} Please refer to PACKAGING INFORMATION for the mounting condition.

ELECTRICAL CHARACTERISTICS

Ta=25 °C

| PARAMETER | SYMBOL | CONDITIONS | MIN. | TYP. | MAX. | UNITS | CIRCUIT |
|------------------------------------|--|--|---------------------|-------------------------------------|-------|-------|---------|
| Bias Voltage ^(*1) | V _{BIAS} | V _{CE} = V _{BIAS} , V _{IN} = V _{OUT(T)} + 0.3V | 2.5 | - | 6.0 | V | ① |
| Input Voltage ^(*2) | V _{IN} | V _{BIAS} = V _{CE} = 3.6V | 1.0 | - | 3.0 | V | ① |
| Output Voltage | V _{OUT(E)} ^(*3) | V _{BIAS} = V _{CE} = 3.6V, V _{IN} = V _{OUT(T)} + 0.3V, I _{OUT} = 100mA | -0.02 | V _{OUT(T)} ^(*4) | +0.02 | V | ① |
| | | | E-0 ^(*5) | | | | |
| Maximum Output Current 1 | I _{OUTMAX 1} | V _{CE} = V _{BIAS} , V _{BIAS} - V _{OUT(T)} ≥ 1.2V V _{IN} = V _{OUT(T)} + 0.5V | 200 | - | - | mA | ① |
| Maximum Output Current 2 | I _{OUTMAX 2} | V _{CE} = V _{BIAS} , V _{BIAS} - V _{OUT(T)} ≥ 1.3V V _{IN} = V _{OUT(T)} + 0.5V | 300 | - | - | mA | ① |
| Maximum Output Current 3 | I _{OUTMAX 3} | V _{CE} = V _{BIAS} , V _{BIAS} - V _{OUT(T)} ≥ 1.5V V _{IN} = V _{OUT(T)} + 0.5V | 400 | - | - | mA | ① |
| Load Regulation | ΔV _{OUT} | V _{BIAS} = V _{CE} = 3.6V, V _{IN} = V _{OUT(T)} + 0.3V, 1mA ≤ I _{OUT} ≤ 300mA | - | 8 | 17 | mV | ① |
| Dropout Voltage 1 | V _{dif1} ^(*7) | V _{BIAS} = V _{CE} , I _{OUT} = 100mA | E-1 ^(*6) | | | mV | ① |
| Dropout Voltage 2 | V _{dif2} ^(*7) | V _{CE} = V _{BIAS} , I _{OUT} = 200mA | E-2 ^(*6) | | | mV | ① |
| Dropout Voltage 3 | V _{dif3} ^(*7) | V _{CE} = V _{BIAS} , I _{OUT} = 300mA | E-3 ^(*6) | | | mV | ① |
| Dropout Voltage 4 | V _{dif4} ^(*7) | V _{CE} = V _{BIAS} , I _{OUT} = 400mA | E-4 ^(*6) | | | mV | ① |
| Supply Current 1 | I _{BIAS} | V _{BIAS} = V _{CE} = 3.6V, V _{IN} = V _{OUT(T)} + 0.3V V _{OUT} = OPEN | 8 | 25 | 45 | μA | ① |
| Supply Current 2 | I _{IN} | V _{BIAS} = V _{CE} = 3.6V, V _{IN} = V _{OUT(T)} + 0.3V V _{OUT} = OPEN | 0.1 | 1.0 | 3.0 | μA | ① |
| Bias Current ^(*10) | I _{BIASMAX} | V _{OUT(T)} ≥ 1.0V V _{BIAS} = V _{CE} = 3.6V, V _{IN} = V _{OUT(T)} V _{OUT} = V _{OUT(T)} - 0.05V | - | 1.0 | 2.5 | mA | ① |
| | | V _{OUT(T)} < 1.0V V _{BIAS} = V _{CE} = 3.6V, V _{IN} = 1.0V V _{OUT} = V _{OUT(T)} - 0.05V | | | | | |
| Stand-by Current 1 | I _{BIAS_STB} | V _{BIAS} = 6.0V, V _{IN} = 3.0V, V _{CE} = V _{SS} | - | 0.01 | 0.10 | μA | ① |
| Stand-by Current 2 | I _{IN_STB} | V _{BIAS} = 6.0V, V _{IN} = 3.0V, V _{CE} = V _{SS} | - | 0.01 | 0.35 | μA | ① |
| Bias Regulation | ΔV _{OUT} / (ΔV _{BIAS} · V _{OUT}) | V _{OUT(T)} ≥ 1.3V V _{OUT(T)} + 1.2V ≤ V _{BIAS} ≤ 6.0V, V _{IN} = V _{OUT(T)} + 0.3V, V _{CE} = V _{BIAS} , I _{OUT} = 1mA | - | 0.01 | 0.3 | %V | ① |
| | | V _{OUT(T)} < 1.3V 2.5V ≤ V _{BIAS} ≤ 6.0V, V _{IN} = V _{OUT(T)} + 0.3V, V _{CE} = V _{BIAS} , I _{OUT} = 1mA | | | | | |
| Input Regulation | ΔV _{OUT} / (ΔV _{IN} · V _{OUT}) | V _{OUT(T)} ≥ 0.90V, V _{OUT(T)} + 0.1V ≤ V _{IN} ≤ 3.0V, V _{BIAS} = V _{CE} = 3.6V, I _{OUT} = 1mA | - | 0.01 | 0.1 | %V | ① |
| | | V _{OUT(T)} < 0.90V, 1.0V ≤ V _{IN} ≤ 3.0V V _{BIAS} = V _{CE} = 3.6V, I _{OUT} = 1mA | | | | | |
| Bias Voltage UVLO | V _{BIAS_UVLO} | V _{CE} = V _{BIAS} , V _{IN} = V _{OUT(T)} + 0.3V, I _{OUT} = 1mA | 1.37 | 2.0 | 2.5 | V | ① |
| Input Voltage UVLO | V _{IN_UVLO} | V _{BIAS} = V _{CE} = 3.6V, I _{OUT} = 1mA | 0.07 | 0.4 | 0.6 | V | ① |
| V _{BIAS} Ripple Rejection | V _{BIAS_PSR} | V _{BIAS} = V _{CE} = 3.6V _{DC} + 0.2V _{p-pAC} , V _{IN} = V _{OUT(T)} + 0.3V, I _{OUT} = 30mA, f = 1kHz | - | 40 | - | dB | ② |
| V _{IN} Ripple Rejection | V _{IN_PSR} | V _{IN} = V _{OUT(T)} + 0.3V _{DC} + 0.2V _{p-pAC} , V _{BIAS} = 3.6V, I _{OUT} = 30mA, f = 1kHz | - | 60 | - | dB | ② |

ELECTRICAL CHARACTERISTICS (Continued)

Ta=25 °C

| PARAMETER | SYMBOL | CONDITIONS | MIN. | TYP. | MAX. | UNITS | CIRCUIT |
|--|---|--|------|-----------|------|----------|---------|
| Output Voltage Temperature Characteristics | $\Delta V_{OUT} / \Delta T_{opr} \cdot V_{OUT}$ | $V_{BIAS}=V_{CE}=3.6V, V_{IN}=V_{OUT(T)}+0.3V, I_{OUT}=30mA, -40^{\circ}C \leq T_{opr} \leq 85^{\circ}C$ | - | ± 100 | - | ppm/°C | ① |
| Limit Current | I_{LIM} | $V_{OUT}=V_{OUT(E)} \times 0.95, V_{BIAS}=V_{CE}=3.6V, V_{IN}=V_{OUT(T)}+0.3V$ | 400 | 550 | - | mA | ① |
| Short Current | I_{SHORT} | $V_{BIAS}=V_{CE}=3.6V, V_{IN}=V_{OUT(T)}+0.3V, V_{OUT}=0V$ | - | 80 | - | mA | ① |
| Thermal Shutdown Detect Temperature | T_{TSD} | Junction Temperature | - | 150 | - | °C | ① |
| Thermal Shutdown Release Temperature | T_{TSR} | Junction Temperature | - | 125 | - | °C | ① |
| Hysteresis Width | $T_{TSD}-T_{TSR}$ | | - | 25 | - | °C | ① |
| CL Auto-Discharge Resistance | R_{dischg} | $V_{BIAS}=3.6V, V_{IN}=V_{OUT(T)}+0.3V, V_{CE}=V_{SS}, V_{OUT}=V_{OUT(T)}$ | 290 | 430 | 610 | Ω | ① |
| CE "H" Level Voltage | V_{CEH} | $V_{BIAS}=3.6V, V_{IN}=V_{OUT(T)}+0.3V$ | 0.75 | - | 6.0 | V | ① |
| CE "L" Level Voltage | V_{CEL} | $V_{BIAS}=3.6V, V_{IN}=V_{OUT(T)}+0.3V$ | - | - | 0.16 | V | ① |
| CE "H" Level Current (A Series) | I_{CEH} | $V_{BIAS}=V_{CE}=6.0V, V_{IN}=V_{OUT(T)}+0.3V$ | 2.4 | - | 8.0 | μA | ① |
| CE "H" Level Current (B Series) | | | -0.1 | - | 0.1 | | |
| CE "L" Level Current | I_{CEL} | $V_{BIAS}=6.0V, V_{CE}=V_{SS}, V_{IN}=V_{OUT(T)}+0.3V$ | -0.1 | - | 0.1 | μA | ① |
| Soft-Start Time (*11) | t_{SS} | $V_{BIAS}=3.6V, V_{IN}=V_{OUT(T)}+0.3V, I_{OUT}=1mA, V_{CE}=0V \rightarrow 3.6V$ | 100 | - | 410 | μs | ③ |

NOTE:

- * 1: Please use Bias voltage V_{BIAS} within the range $V_{BIAS}-V_{OUT(E)}^{(*)} \geq 1.2V$
- * 2: Please use Input voltage V_{IN} within the range $V_{IN} \leq V_{BIAS}$
- * 3: $V_{OUT(E)}$ = Effective output voltage (Refer to the voltage chart E-0 and E-1)
- * 4: $V_{OUT(T)}$ = Specified output voltage
- * 5: E-0 = Please refer to the table named OUTPUT VOLTAGE CHART
- * 6: E-1 = Please refer to the table named DROPOUT VOLTAGE CHART
- * 7: $V_{dif} = \{V_{IN1}^{(*)}-V_{OUT1}^{(*)}\}$.
- * 8: V_{IN1} = The input voltage when V_{OUT1} appears as input voltage is gradually decreased.
- * 9: V_{OUT1} = A voltage equal to 98% of the output voltage while maintaining an amply stabilized output voltage when $V_{IN}=V_{BIAS}$ at $V_{BIAS}<3.0V$, and $V_{IN}=3.0V$ at $V_{BIAS} \geq 3.0V$ is input to the V_{IN} pin.
- * 10: $I_{BIASMAX}$ = A supply current at the V_{BIAS} pin providing for the output current (I_{OUT}).
- * 11: t_{SS} is defined as a time V_{OUT} reaches $V_{OUT(E)} \times 0.9V$ from the time when CE H threshold 0.75V is input to the CE pin.

OUTPUT VOLTAGE CHART

| NOMINAL OUTPUT VOLTAGE (V) | E-0 | |
|----------------------------|--------------------|-------|
| | OUTPUT VOLTAGE (V) | |
| | V_{OUT} | |
| $V_{OUT(T)}$ | MIN. | MAX. |
| 0.70 | 0.680 | 0.720 |
| 0.75 | 0.730 | 0.770 |
| 0.80 | 0.780 | 0.820 |
| 0.85 | 0.830 | 0.870 |
| 0.90 | 0.880 | 0.920 |
| 0.95 | 0.930 | 0.970 |
| 1.00 | 0.980 | 1.020 |
| 1.05 | 1.030 | 1.070 |
| 1.10 | 1.080 | 1.120 |
| 1.15 | 1.130 | 1.170 |
| 1.20 | 1.180 | 1.220 |
| 1.25 | 1.230 | 1.270 |

| NOMINAL OUTPUT VOLTAGE (V) | E-0 | |
|----------------------------|--------------------|-------|
| | OUTPUT VOLTAGE (V) | |
| | V_{OUT} | |
| $V_{OUT(T)}$ | MIN. | MAX. |
| 1.30 | 1.280 | 1.320 |
| 1.35 | 1.330 | 1.370 |
| 1.40 | 1.380 | 1.420 |
| 1.45 | 1.430 | 1.470 |
| 1.50 | 1.480 | 1.520 |
| 1.55 | 1.530 | 1.570 |
| 1.60 | 1.580 | 1.620 |
| 1.65 | 1.630 | 1.670 |
| 1.70 | 1.680 | 1.720 |
| 1.75 | 1.730 | 1.770 |
| 1.80 | 1.780 | 1.820 |

■ DROPOUT VOLTAGE CHART

| NOMINAL OUTPUT VOLTAGE (V) | E-1 | | | | | | | | | | | | | | | |
|----------------------------------|------------------------|---------------------------------------|------|---------------|------|------------------------|---------------|------|------------------------|---------------|------|------------------------|---------------|------|------------------------|----------|
| | DROPOUT VOLTAGE 1 (mV) | | | | | | | | | | | | | | | |
| | Vdif 1 | | | | | | | | | | | | | | | |
| | VBIAS=3.0 (V) | | | VBIAS=3.3 (V) | | | VBIAS=3.6 (V) | | | VBIAS=4.2 (V) | | | VBIAS=5.0 (V) | | | |
| | V _{OUT(T)} | V _{gs} ^(*) (V) | | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) |
| TYP. | | MAX. | TYP. | MAX. | TYP. | | MAX. | TYP. | | MAX. | TYP. | | MAX. | TYP. | | MAX. |
| 0.70 | 2.30 | 40 | 300 | 2.60 | 35 | 300 | 2.90 | 33 | 300 | 3.50 | 30 | 300 | 4.30 | 27 | 300 | |
| 0.75 | 2.25 | 41 | 250 | 2.55 | 36 | 250 | 2.85 | 34 | 250 | 3.45 | 31 | 250 | 4.25 | 28 | 250 | |
| 0.80 | 2.20 | | 200 | 2.50 | | 200 | 2.80 | | 200 | | | 3.40 | 200 | | 4.20 | 200 |
| 0.85 | 2.15 | 42 | 150 | 2.45 | 38 | 150 | 2.75 | 34 | 150 | 3.35 | 31 | 150 | 4.15 | 28 | 150 | |
| 0.90 | 2.10 | | 100 | 2.40 | | 100 | 2.70 | | 100 | | | 3.30 | 100 | | 4.10 | 100 |
| 0.95 | 2.05 | 43 | 68 | 2.35 | 40 | 61 | 2.65 | 35 | 56 | 3.25 | 32 | 50 | 4.05 | 28 | 50 | |
| 1.00 | 2.00 | | 2.30 | 2.60 | | 3.20 | 49 | | 4.00 | | | 44 | | | | |
| 1.05 | 1.95 | 46 | 72 | 2.25 | 41 | 63 | 2.55 | 36 | 58 | 3.15 | 32 | 50 | 3.95 | 29 | 45 | |
| 1.10 | 1.90 | | 2.20 | 2.50 | | 3.10 | 3.90 | | | | | | | | | |
| 1.15 | 1.85 | 48 | 75 | 2.15 | 42 | 65 | 2.45 | 38 | 59 | 3.05 | 32 | 51 | 3.85 | 29 | 46 | |
| 1.20 | 1.80 | | 2.10 | 2.40 | | 3.00 | 3.80 | | | | | | | | | |
| 1.25 | 1.75 | 51 | 81 | 2.05 | 43 | 68 | 2.35 | 40 | 61 | 2.95 | 33 | 52 | 3.75 | 29 | 47 | |
| 1.30 | 1.70 | | 2.00 | 2.30 | | 2.90 | 3.70 | | | | | | | | | |
| 1.35 | 1.65 | 54 | 87 | 1.95 | 46 | 72 | 2.25 | 41 | 63 | 2.85 | 34 | 53 | 3.65 | 30 | 47 | |
| 1.40 | 1.60 | | 1.90 | 2.20 | | 2.80 | 3.60 | | | | | | | | | |
| 1.45 | 1.55 | 57 | 92 | 1.85 | 48 | 75 | 2.15 | 42 | 65 | 2.75 | 34 | 54 | 3.55 | 30 | 48 | |
| 1.50 | 1.50 | | 1.80 | 2.10 | | 2.70 | 3.50 | | | | | | | | | |
| 1.55 | 1.45 | 61 | 94 | 1.75 | 51 | 81 | 2.05 | 43 | 68 | 2.65 | 35 | 56 | 3.45 | 31 | 48 | |
| 1.60 | 1.40 | 63 | 97 | 1.70 | | 2.00 | 2.60 | | 3.40 | | | | | | | |
| 1.65 | 1.35 | 67 | 104 | 1.65 | 54 | 87 | 1.95 | 46 | 72 | 2.55 | 36 | 58 | 3.35 | 31 | 49 | |
| 1.70 | 1.30 | 70 | 113 | 1.60 | | 1.90 | 2.50 | | 3.30 | | | | | | | |
| 1.75 | 1.25 | 74 | 131 | 1.55 | 57 | 92 | 1.85 | 48 | 75 | 2.45 | 38 | 59 | 3.25 | 32 | 49 | |
| 1.80 | 1.20 | 79 | 154 | 1.50 | | 1.80 | 2.40 | | 3.20 | | | | | | | |

*1): V_{gs} is a Gate –Source voltage of the driver transistor that is defined as the value of V_{BIAS} – V_{OUT(T)}.

■ DROPOUT VOLTAGE CHART (Continued)

| NOMINAL OUTPUT VOLTAGE (V) | E-2 | | | | | | | | | | | | | | |
|----------------------------------|----------------------------|---------------------------------------|----------|----------------------------|------------------------|----------|----------------------------|------------------------|----------|----------------------------|------------------------|----------|----------------------------|------------------------|----------|
| | DROPOUT VOLTAGE 2 (mV) | | | | | | | | | | | | | | |
| | Vdif 2 | | | | | | | | | | | | | | |
| | V _{BIAS} = 3.0(V) | | | V _{BIAS} = 3.3(V) | | | V _{BIAS} = 3.6(V) | | | V _{BIAS} = 4.2(V) | | | V _{BIAS} = 5.0(V) | | |
| | V _{OUT(T)} | V _{gs} ^(*) (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) |
| TYP. | | | MAX. | TYP. | | MAX. | TYP. | | MAX. | TYP. | | MAX. | TYP. | | MAX. |
| 0.70 | 2.30 | 81 | 300 | 2.60 | 74 | 300 | 2.90 | 68 | 300 | 3.50 | 62 | 300 | 4.30 | 57 | 300 |
| 0.75 | 2.25 | 85 | 250 | 2.55 | 76 | 250 | 2.85 | 70 | 250 | 3.45 | 63 | 250 | 4.25 | 58 | 250 |
| 0.80 | 2.20 | | 200 | 2.50 | | 200 | 2.80 | | 200 | 3.40 | | 200 | 4.20 | | 200 |
| 0.85 | 2.15 | 88 | 150 | 2.45 | 78 | 150 | 2.75 | 72 | 150 | 3.35 | 63 | 150 | 4.15 | 58 | 150 |
| 0.90 | 2.10 | | 131 | 2.40 | | 117 | 2.70 | | 110 | 3.30 | | 100 | 4.10 | | 100 |
| 0.95 | 2.05 | 90 | 139 | 2.35 | 81 | 123 | 2.65 | 74 | 111 | 3.25 | 64 | 98 | 4.05 | 58 | 88 |
| 1.00 | 2.00 | | 2.30 | 2.60 | | 3.20 | 4.00 | | | | | | | | |
| 1.05 | 1.95 | 96 | 146 | 2.25 | 85 | 127 | 2.55 | 76 | 114 | 3.15 | 65 | 101 | 3.95 | 59 | 90 |
| 1.10 | 1.90 | | 2.20 | 2.50 | | 3.10 | 3.90 | | | | | | | | |
| 1.15 | 1.85 | 101 | 154 | 2.15 | 88 | 131 | 2.45 | 78 | 117 | 3.05 | 67 | 103 | 3.85 | 59 | 91 |
| 1.20 | 1.80 | | 2.10 | 2.40 | | 3.00 | 3.80 | | | | | | | | |
| 1.25 | 1.75 | 108 | 170 | 2.05 | 90 | 139 | 2.35 | 81 | 123 | 2.95 | 68 | 106 | 3.75 | 60 | 92 |
| 1.30 | 1.70 | | 2.00 | 2.30 | | 2.90 | 3.70 | | | | | | | | |
| 1.35 | 1.65 | 115 | 179 | 1.95 | 96 | 146 | 2.25 | 85 | 127 | 2.85 | 70 | 108 | 3.65 | 61 | 93 |
| 1.40 | 1.60 | | 1.90 | 2.20 | | 2.80 | 3.60 | | | | | | | | |
| 1.45 | 1.55 | 122 | 192 | 1.85 | 101 | 154 | 2.15 | 88 | 131 | 2.75 | 72 | 110 | 3.55 | 62 | 94 |
| 1.50 | 1.50 | | 1.80 | 2.10 | | 2.70 | 3.50 | | | | | | | | |
| 1.55 | 1.45 | 129 | 197 | 1.75 | 108 | 170 | 2.05 | 90 | 139 | 2.65 | 74 | 111 | 3.45 | 63 | 95 |
| 1.60 | 1.40 | 135 | 206 | 1.70 | | 2.00 | 2.60 | | 3.40 | | | | | | |
| 1.65 | 1.35 | 145 | 223 | 1.65 | 115 | 179 | 1.95 | 96 | 146 | 2.55 | 76 | 114 | 3.35 | 63 | 97 |
| 1.70 | 1.30 | 154 | 248 | 1.60 | | 1.90 | 2.50 | | 3.30 | | | | | | |
| 1.75 | 1.25 | 165 | 293 | 1.55 | 122 | 192 | 1.85 | 101 | 154 | 2.45 | 78 | 117 | 3.25 | 64 | 98 |
| 1.80 | 1.20 | 175 | 353 | 1.50 | | 1.80 | 2.40 | | 3.20 | | | | | | |

*1): V_{gs} is a Gate –Source voltage of the driver transistor that is defined as the value of V_{BIAS} – V_{OUT(T)}.

■ DROPOUT VOLTAGE CHART (Continued)

| NOMINAL OUTPUT VOLTAGE (V) | E-3 | | | | | | | | | | | | | | |
|----------------------------------|---------------------------|---------------------------------------|----------|---------------------------|------------------------|----------|---------------------------|------------------------|----------|---------------------------|------------------------|----------|---------------------------|------------------------|----------|
| | DROPOUT VOLTAGE 3 (mV) | | | | | | | | | | | | | | |
| | Vdif 3 | | | | | | | | | | | | | | |
| | V _{BIAS} =3.0(V) | | | V _{BIAS} =3.3(V) | | | V _{BIAS} =3.6(V) | | | V _{BIAS} =4.2(V) | | | V _{BIAS} =5.0(V) | | |
| | V _{OUT(T)} | V _{gs} ^(*) (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) |
| TYP. | | MAX. | TYP. | MAX. | TYP. | MAX. | TYP. | MAX. | TYP. | MAX. | TYP. | MAX. | TYP. | MAX. | |
| 0.70 | 2.30 | 130 | 300 | 2.60 | 115 | 300 | 2.90 | 107 | 300 | 3.50 | 95 | 300 | 4.30 | 89 | 300 |
| 0.75 | 2.25 | 134 | 250 | 2.55 | 117 | 250 | 2.85 | 109 | 250 | 3.45 | 96 | 250 | 4.25 | 90 | 250 |
| 0.80 | 2.20 | | 200 | 2.50 | | 200 | 2.80 | | 200 | 3.40 | | 200 | 4.20 | | 200 |
| 0.85 | 2.15 | 138 | 204 | 2.45 | 119 | 181 | 2.75 | 111 | 167 | 3.35 | 97 | 150 | 4.15 | 90 | 150 |
| 0.90 | 2.10 | | | 2.40 | | | 2.70 | | | 3.30 | | 148 | 4.10 | | 132 |
| 0.95 | 2.05 | 145 | 216 | 2.35 | 130 | 190 | 2.65 | 115 | 170 | 3.25 | 98 | 151 | 4.05 | 91 | 134 |
| 1.00 | 2.00 | | | 2.30 | | | 2.60 | | | 3.20 | | 4.00 | | | |
| 1.05 | 1.95 | 153 | 227 | 2.25 | 134 | 197 | 2.55 | 117 | 176 | 3.15 | 101 | 153 | 3.95 | 92 | 137 |
| 1.10 | 1.90 | | | 2.20 | | | 2.50 | | | 3.10 | | 3.90 | | | |
| 1.15 | 1.85 | 161 | 239 | 2.15 | 138 | 204 | 2.45 | 119 | 181 | 3.05 | 105 | 155 | 3.85 | 93 | 139 |
| 1.20 | 1.80 | | | 2.10 | | | 2.40 | | | 3.00 | | 3.80 | | | |
| 1.25 | 1.75 | 173 | 264 | 2.05 | 145 | 216 | 2.35 | 130 | 190 | 2.95 | 107 | 159 | 3.75 | 93 | 140 |
| 1.30 | 1.70 | | | 2.00 | | | 2.30 | | | 2.90 | | 3.70 | | | |
| 1.35 | 1.65 | 184 | 289 | 1.95 | 153 | 227 | 2.25 | 134 | 197 | 2.85 | 109 | 163 | 3.65 | 94 | 141 |
| 1.40 | 1.60 | | | 1.90 | | | 2.20 | | | 2.80 | | 3.60 | | | |
| 1.45 | 1.55 | 196 | 313 | 1.85 | 161 | 239 | 2.15 | 138 | 204 | 2.75 | 111 | 167 | 3.55 | 95 | 142 |
| 1.50 | 1.50 | | | 1.80 | | | 2.10 | | | 2.70 | | 3.50 | | | |
| 1.55 | 1.45 | 209 | 323 | 1.75 | 173 | 264 | 2.05 | 145 | 216 | 2.65 | 115 | 170 | 3.45 | 96 | 145 |
| 1.60 | 1.40 | 222 | 344 | 1.70 | | | 2.00 | | | 2.60 | | 3.40 | | | |
| 1.65 | 1.35 | 239 | 388 | 1.65 | 184 | 289 | 1.95 | 153 | 227 | 2.55 | 117 | 176 | 3.35 | 97 | 148 |
| 1.70 | 1.30 | 256 | 442 | 1.60 | | | 1.90 | | | 2.50 | | 3.30 | | | |
| 1.75 | 1.25 | - | - | 1.55 | 196 | 313 | 1.85 | 161 | 239 | 2.45 | 119 | 181 | 3.25 | 98 | 151 |
| 1.80 | 1.20 | | | 1.50 | | | 1.80 | | | 2.40 | | 3.20 | | | |

*1): V_{gs} is a Gate –Source voltage of the driver transistor that is defined as the value of V_{BIAS} – V_{OUT(T)}.

■ DROPOUT VOLTAGE CHART (Continued)

| NOMINAL OUTPUT VOLTAGE (V) | E-4 | | | | | | | | | | | | | | |
|----------------------------------|---------------------------|---------------------------------------|----------|---------------------------|------------------------|----------|---------------------------|------------------------|----------|---------------------------|------------------------|----------|---------------------------|------------------------|----------|
| | DROPOUT VOLTAGE 4 (mV) | | | | | | | | | | | | | | |
| | Vdif 4 | | | | | | | | | | | | | | |
| | V _{BIAS} =3.0(V) | | | V _{BIAS} =3.3(V) | | | V _{BIAS} =3.6(V) | | | V _{BIAS} =4.2(V) | | | V _{BIAS} =5.0(V) | | |
| | V _{OUT(T)} | V _{gs} ^(*) (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) | | V _{gs} (V) | Vdif(mV) |
| TYP. | | MAX. | TYP. | MAX. | TYP. | MAX. | TYP. | MAX. | TYP. | MAX. | TYP. | MAX. | TYP. | MAX. | |
| 0.70 | 2.30 | 189 | 300 | 2.60 | 157 | 300 | 2.90 | 146 | 300 | 3.50 | 129 | 300 | 4.30 | 116 | 300 |
| 0.75 | 2.25 | 195 | 277 | 2.55 | 164 | 272 | 2.85 | 150 | 250 | 3.45 | 131 | 250 | 4.25 | 118 | 250 |
| 0.80 | 2.20 | | | 2.50 | | | 2.80 | | | 3.40 | | 246 | | | 4.20 |
| 0.85 | 2.15 | 201 | 277 | 2.45 | 170 | 272 | 2.75 | 153 | 250 | 3.35 | 134 | 246 | 4.15 | 119 | 231 |
| 0.90 | 2.10 | | | 2.40 | | | 2.70 | | | 3.30 | | 4.10 | | | |
| 0.95 | 2.05 | 206 | 277 | 2.35 | 189 | 272 | 2.65 | 157 | 250 | 3.25 | 136 | 246 | 4.05 | 121 | 231 |
| 1.00 | 2.00 | | | 2.30 | | | 2.60 | | | 3.20 | | 4.00 | | | |
| 1.05 | 1.95 | 218 | 277 | 2.25 | 195 | 272 | 2.55 | 164 | 250 | 3.15 | 139 | 246 | 3.95 | 125 | 231 |
| 1.10 | 1.90 | | | 2.20 | | | 2.50 | | | 3.10 | | 3.90 | | | |
| 1.15 | 1.85 | 231 | 227 | 2.15 | 201 | 272 | 2.45 | 170 | 250 | 3.05 | 142 | 246 | 3.85 | 128 | 231 |
| 1.20 | 1.80 | | 334 | 2.10 | | 277 | 2.40 | | 248 | 3.00 | | 215 | 3.80 | | 189 |
| 1.25 | 1.75 | 248 | 376 | 2.05 | 206 | 296 | 2.35 | 189 | 255 | 2.95 | 146 | 219 | 3.75 | 128 | 191 |
| 1.30 | 1.70 | | | 2.00 | | | 2.30 | | | 2.90 | | | 3.70 | | |
| 1.35 | 1.65 | 264 | 418 | 1.95 | 218 | 315 | 2.25 | 195 | 266 | 2.85 | 150 | 224 | 3.65 | 129 | 193 |
| 1.40 | 1.60 | | | 1.90 | | | 2.20 | | | 2.80 | | | 3.60 | | |
| 1.45 | 1.55 | 281 | 460 | 1.85 | 231 | 334 | 2.15 | 201 | 277 | 2.75 | 153 | 228 | 3.55 | 129 | 195 |
| 1.50 | 1.50 | | | 1.80 | | | 2.10 | | | 2.70 | | | 3.50 | | |
| 1.55 | 1.45 | - | - | 1.75 | 248 | 376 | 2.05 | 206 | 296 | 2.65 | 157 | 234 | 3.45 | 131 | 198 |
| 1.60 | 1.40 | | | 1.70 | | | 2.00 | | | 2.60 | | | 3.40 | | |
| 1.65 | 1.35 | - | - | 1.65 | 264 | 418 | 1.95 | 218 | 315 | 2.55 | 164 | 241 | 3.35 | 134 | 202 |
| 1.70 | 1.30 | | | 1.60 | | | 1.90 | | | 2.50 | | | 3.30 | | |
| 1.75 | 1.25 | - | - | 1.55 | 281 | 460 | 1.85 | 231 | 334 | 2.45 | 170 | 248 | 3.25 | 136 | 205 |
| 1.80 | 1.20 | | | 1.50 | | | 1.80 | | | 2.40 | | | 3.20 | | |

*1): V_{gs} is a Gate –Source voltage of the driver transistor that is defined as the value of V_{BIAS} – V_{OUT(T)}.

■ OPERATIONAL EXPLANATION

<Voltage Regulator>

The voltage divided by resistors R1 & R2 is compared with the internal reference voltage by the error amplifier. The N-channel MOSFET which is connected to the V_{OUT} pin is then driven by the subsequent output signal. The output voltage at the V_{OUT} pin is controlled & stabilized by a system of negative feedback.

V_{BIAS} pin is power supply pin for output voltage control circuit, protection circuit and CE circuit. When output current increase, the V_{BIAS} pin supplies output current also. V_{IN} pin is connected to a driver transistor and provides output current.

In order to obtain highly efficient output current through low on-resistance, please take enough V_{gs} (=V_{BIAS} - V_{OUT(T)}) of the driver transistor. Output current triggers operation of constant current limiter and fold-back circuit, heat generation triggers operation of thermal shutdown circuit, the driver transistor circuit is forced OFF when V_{BIAS} or V_{IN} voltage goes lower than UVLO voltage. Further, the IC's internal circuitry can be shutdown via the CE pin's signal.

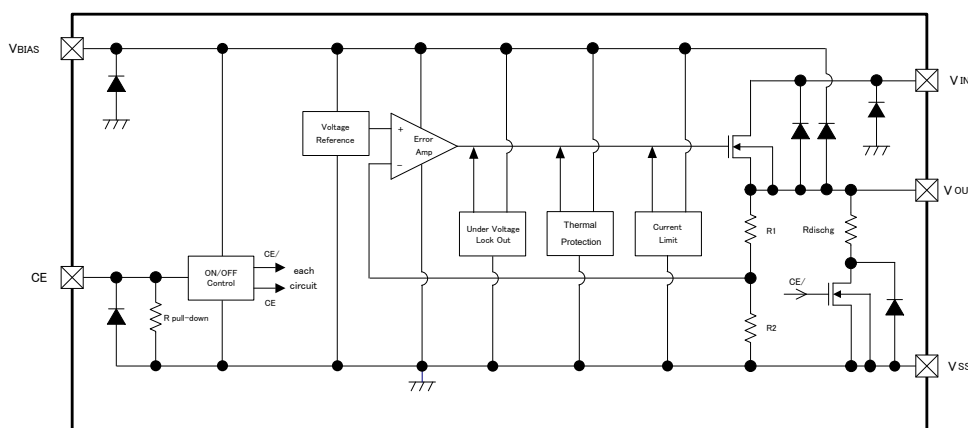


Figure1: XC6601A series

<Low ESR Capacitor>

With the XC6601 series, a stable output voltage is achievable even if used with low ESR capacitors, as a phase compensation circuit is built-in. The output capacitor (C_L) should be connected as close to V_{OUT} pin and V_{SS} pin to obtain stable phase compensation. Values required for the phase compensation are as the table below.

For a stable power input, please connect an bias capacitor (C_{BIAS}) of 1.0 μF between the V_{BIAS} pin and the V_{SS} pin. Also, please connect an input capacitor (C_{IN}) of 1.0 μF between the V_{IN} pin and the V_{SS} pin. In order to ensure the stable phase compensation while avoiding run-out of values, please use the capacitor (C_{BIAS}, C_{IN}, C_L) which does not depend on bias or temperature too much. The table below shows recommended values of C_{BIAS}, C_{IN}, C_L.

| SETTING VOLTAGE | BIAS CAPACITOR | INPUT CAPACITOR | OUTPUT CAPACITOR |
|-----------------|--------------------------|------------------------|-----------------------|
| | C _{BIAS} | C _{IN} | C _L |
| 0.7V ~ 1.8V | C _{BIAS} =1.0μF | C _{IN} =1.0μF | C _L =4.7μF |

Recommended Values of C_{BIAS}, C_{IN}, C_L

OPERATIONAL EXPLANATION (Continued)

<Soft-Start Function>

With the XC6601, the inrush current from V_{IN} to V_{OUT} for charging C_L at start-up can be reduced and makes the V_{IN} stable. The soft-start time is optimized to $240 \mu s$ (TYP.) at $V_{OUT}=1.2V$ internally. Soft-start time is defined as the V_{OUT} reaches 90% of $V_{OUT(E)}$ from the time when CE H threshold $0.75V$ is input to the CE pin.

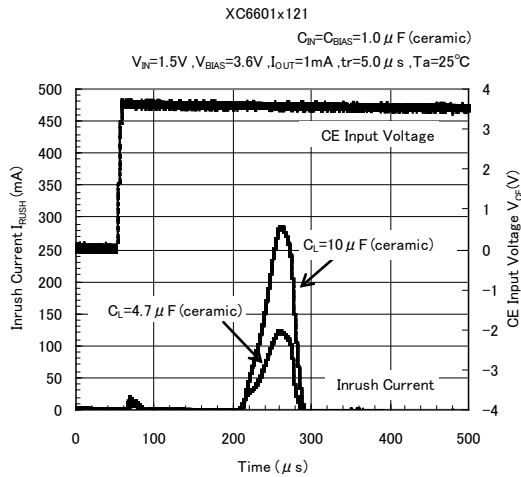


Figure2: Example of the inrush current wave form at IC start-up.

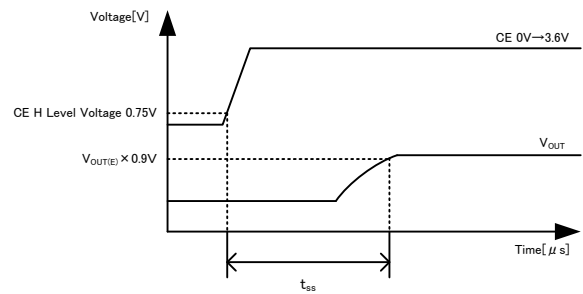


Figure3: Timing chart at IC start-up

<CL High Speed Auto-Discharge>

XC6601 series can quickly discharge the electric charge at the output capacitor (C_L) when a low signal to the EN pin which enables a whole IC circuit put into OFF state, is inputted via the N-channel transistor located between the V_{OUT} pin and the V_{SS} pin. When the IC is disabled, electric charge at the output capacitor (C_L) is quickly discharged so that it could avoid malfunction. At that time, C_L discharge resistance is depended on a bias voltage. Discharge time of the output capacitor (C_L) is set by the C_L auto-discharge resistance (R) and the output capacitor (C_L). By setting time constant of a C_L auto-discharge resistance value [R] and an output capacitor value (C_L) as τ ($\tau = C \times R$), the output voltage after discharge via the N channel transistor is calculated by the following formulas.

$$V = V_{OUT} \times e^{-t/\tau}, \text{ or } t = \tau \ln(V_{OUT(E)} / V)$$

V : Output voltage after discharge, $V_{OUT(E)}$: Output voltage, t : Discharge time,

τ : C_L auto-discharge resistance $R \times$ Output capacitor (C_L) value C

<Current Limit, Short-Circuit Protection>

The XC6601 series' fold-back circuit operates as an output current limiter and a short protection of the output pin. When the load current reaches the current limit level, the fixed current limiter circuit operates and output voltage drops. When the output pin is shorted to the V_{SS} level, current flows about 80mA.

<Thermal Shutdown Circuit (TSD) >

When the junction temperature of the built-in driver transistor reaches the temperature limit level ($150^\circ C$ TYP.), the thermal shutdown circuit operates and the driver transistor will be set to OFF. The IC resumes its operation when the thermal shutdown function is released and the IC's operation is automatically restored because the junction temperature drops to the level of the thermal shutdown release temperature ($125^\circ C$ TYP.).

■ OPERATIONAL EXPLANATION (Continued)

<Under Voltage Lock Out (UVLO) >

When the V_{BIAS} pin voltage drops below 2.0V (TYP.) or V_{IN} pin voltage drops below 0.4V (TYP.), the output driver transistor is forced OFF by UVLO function to prevent false output caused by unstable operation of the internal circuitry. When the V_{BIAS} pin voltage rise at 2.2V (TYP.) or the V_{IN} pin voltage rises at 0.4V (TYP.), the UVLO function is released. The driver transistor is turned in the ON state and start to operate voltage regulation.

<CE Pin>

The IC internal circuitry can be shutdown via the signal from the CE pin with the XC6601 series. In shutdown mode, output at the V_{OUT} pin will be pulled down to the V_{SS} level via R1 & R2. However, as for the XC6601 series, the CL auto-discharge resistor is connected in parallel to R1 and R2 while the power supply is applied to the V_{IN} pin. Therefore, time until the V_{OUT} pin reaches the V_{SS} level becomes short.

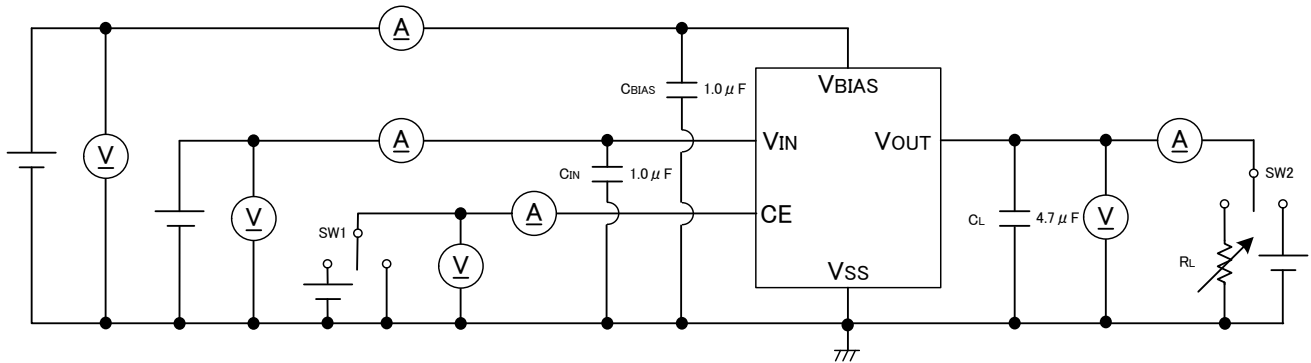
The CE pin of XC6601A has pull-down circuitry so that CE input current increase during IC operation. The CE pin of XC6601B does not have pull-down circuitry so that logic is not fixed when the CE pin is open. If the CE pin voltage is taken from V_{BIAS} pin or V_{SS} pin then logic is fixed and the IC will operate normally. However, supply current may increase as a result of through current in the IC's internal circuitry when medium voltage is input.

■ NOTE ON USE

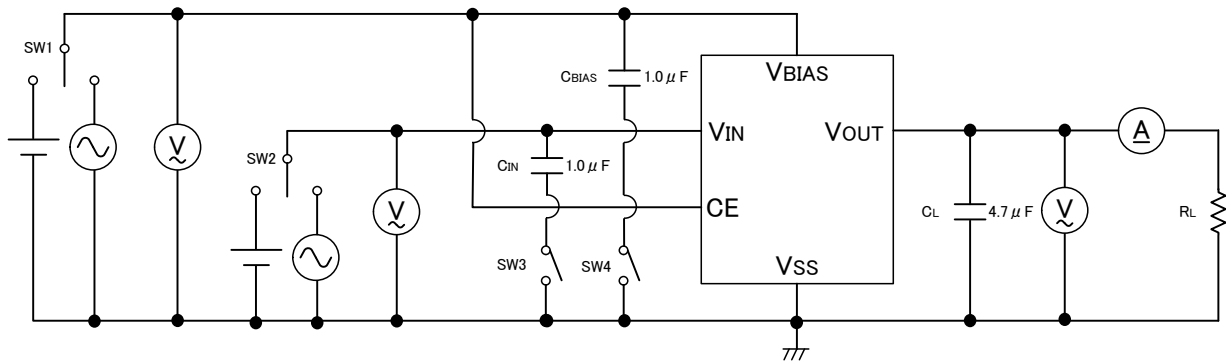
1. Please use this IC within the stated absolute maximum ratings. The IC is liable to malfunction should the ratings be exceeded.
2. Where wiring impedance is high, operations may become unstable due to noise and/or phase lag depending on output current. Please keep the resistance low between V_{BIAS} and V_{SS} wiring or V_{IN} and V_{SS} wiring in particular.
3. Please wire the bias capacitor (C_{BIAS}), input capacitor (C_{IN}) and the output capacitor (C_L) as close to the IC as possible.
4. Capacitance values of these capacitors (C_{BIAS} , C_{IN} , C_L) are decreased by the influences of bias voltage and ambient temperature. Care shall be taken for capacitor selection to ensure stability of phase compensation from the point of ESR influence.
5. In case of the output capacitor more than $C_L=22\mu F$ is used, ringing of input current occurs when rising time.
6. V_{IN} and CE should be applied at least $10\mu s$ after the bias voltage V_{BIAS} reaches the requested voltage. If V_{IN} and CE are applied within $10\mu s$, inrush current like 1A may occurs.

TEST CIRCUITS

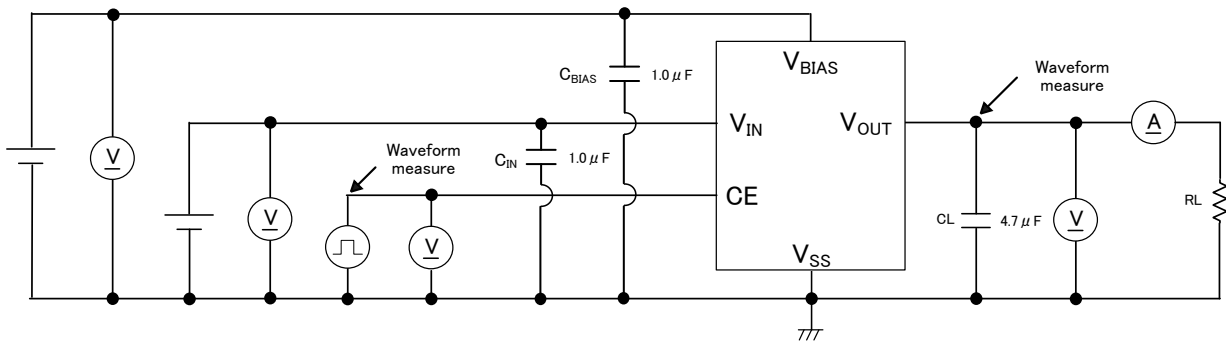
Circuit ①



Circuit ②



Circuit ③



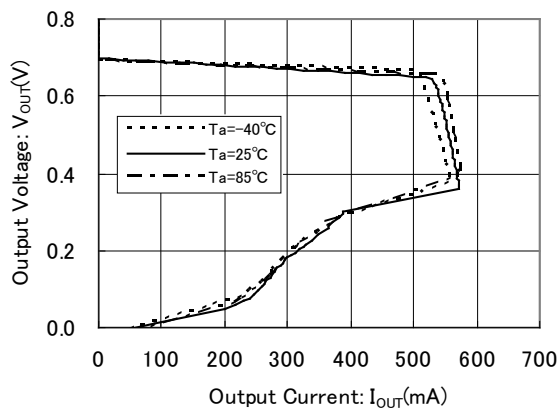
* For the timing chart, please refer to page 12 <Soft-Start Function>.

TYPICAL PERFORMANCE CHARACTERISTICS

(1) Output Voltage vs. Output Current

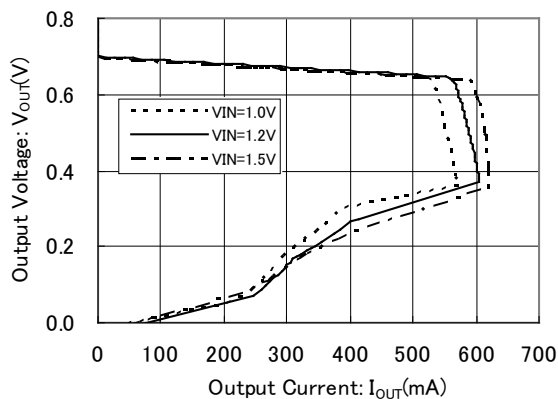
XC6601B071MR

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=3.6\text{V}$, $V_{IN}=1.0\text{V}$



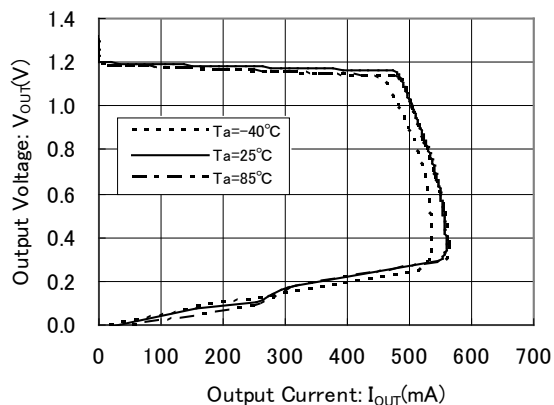
XC6601B071MR

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=3.6\text{V}$, $T_a=25^\circ\text{C}$



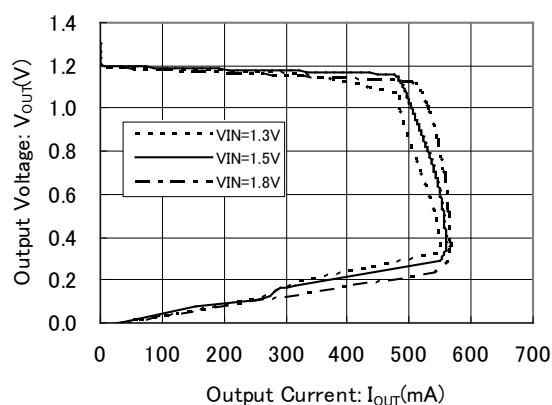
XC6601B121MR

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=3.6\text{V}$, $V_{IN}=1.5\text{V}$



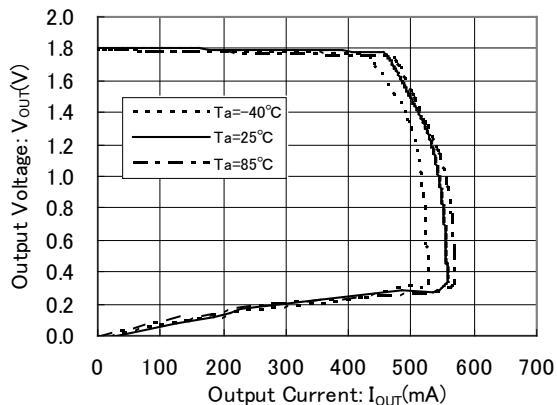
XC6601B121MR

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=3.6\text{V}$, $T_a=25^\circ\text{C}$



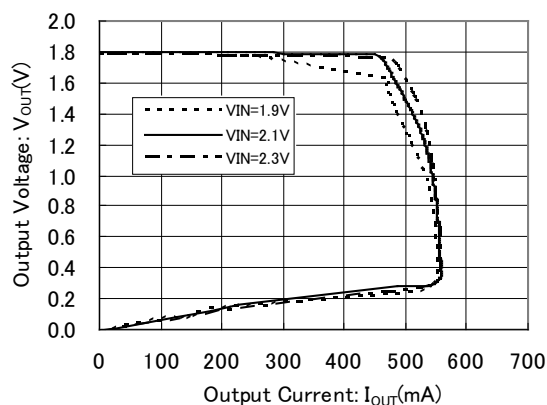
XC6601B181MR

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=3.6\text{V}$, $V_{IN}=2.1\text{V}$



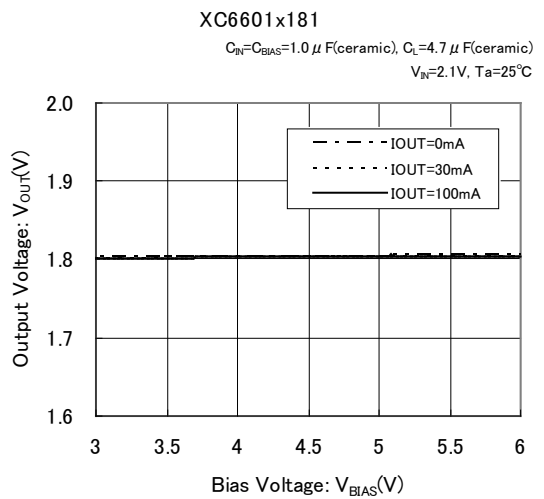
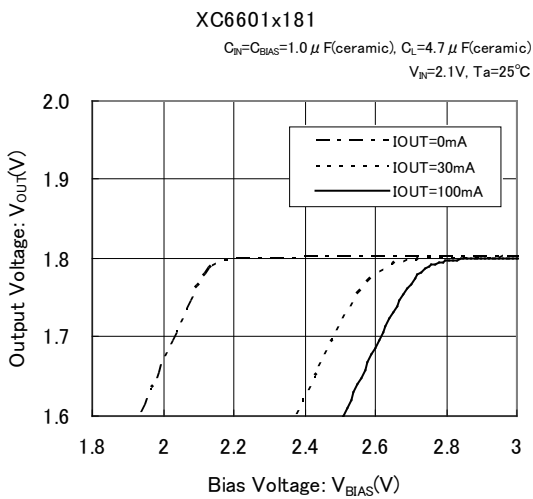
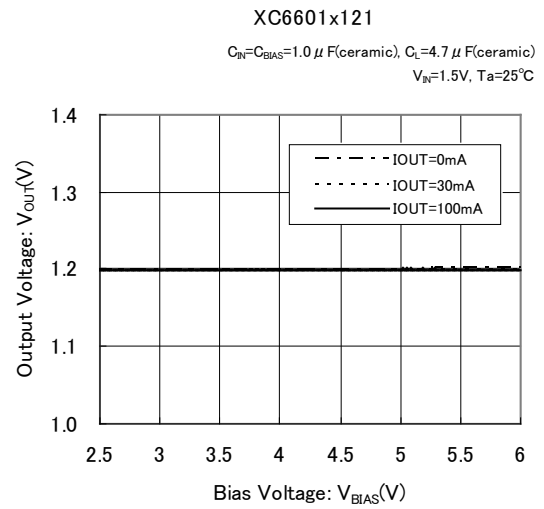
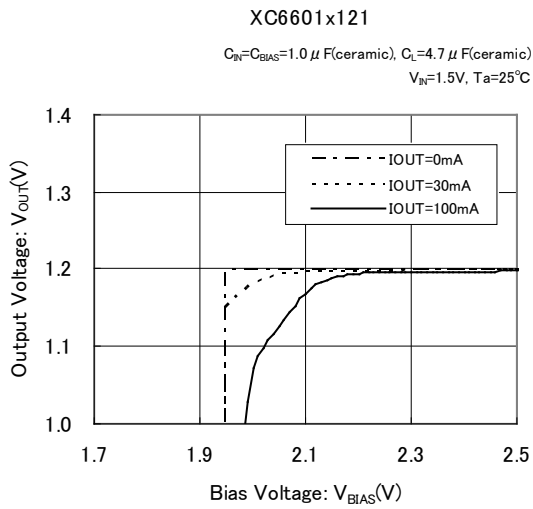
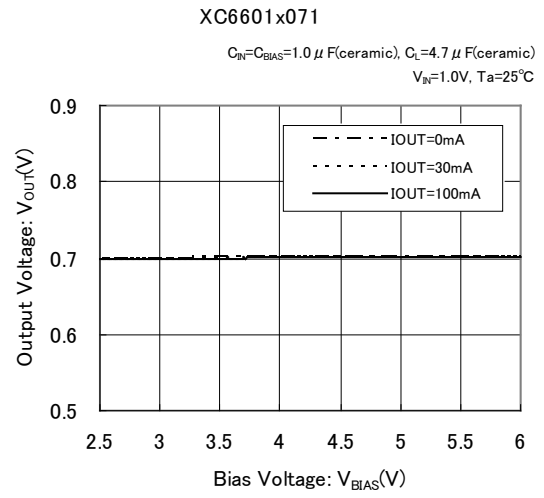
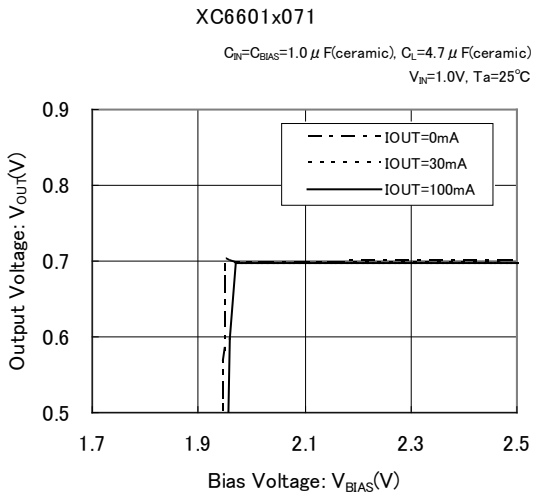
XC6601B181MR

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=3.6\text{V}$, $T_a=25^\circ\text{C}$



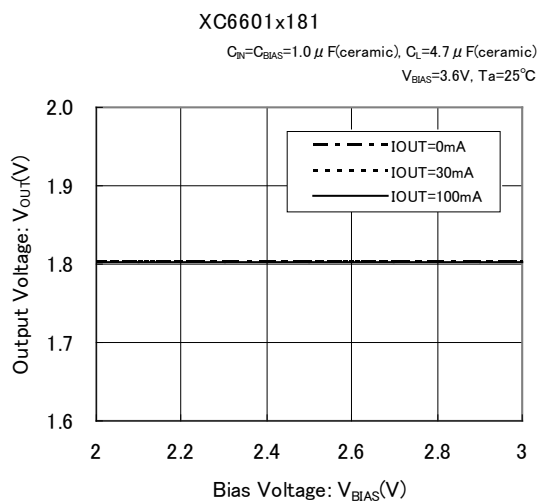
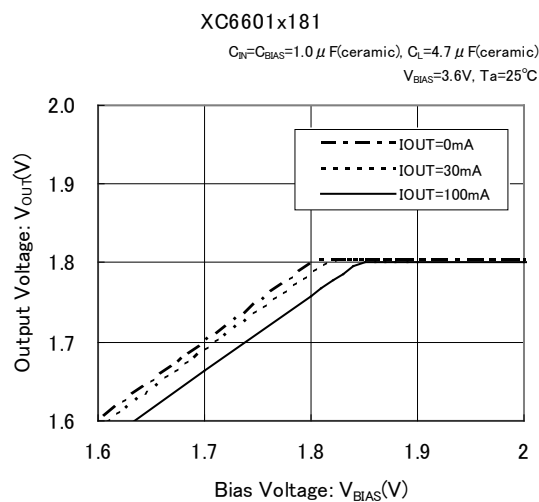
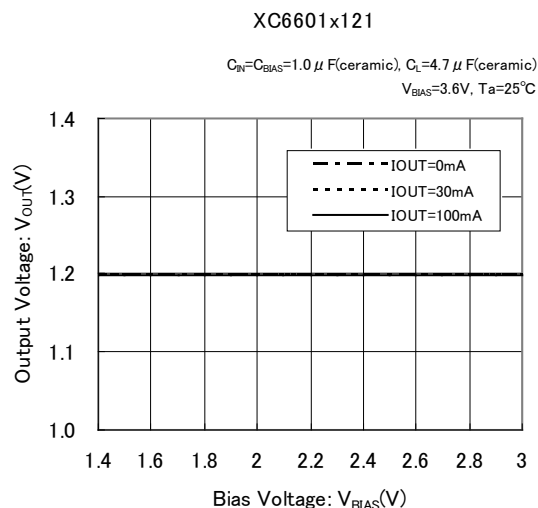
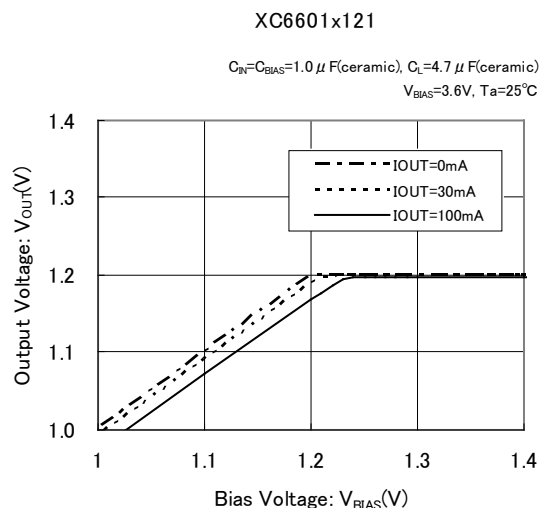
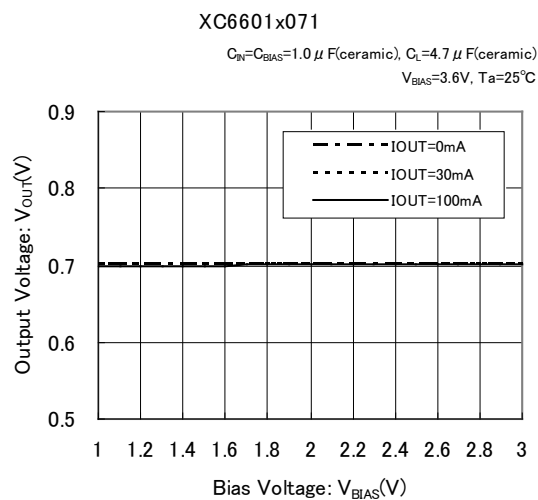
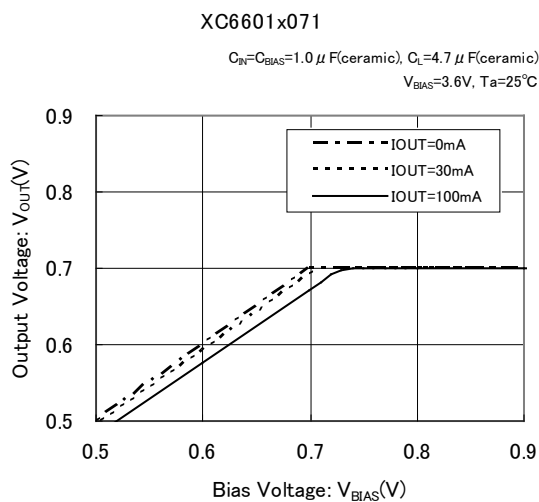
TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(2) Output Voltage vs. Bias Voltage



■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(3) Output Voltage vs. Input Voltage

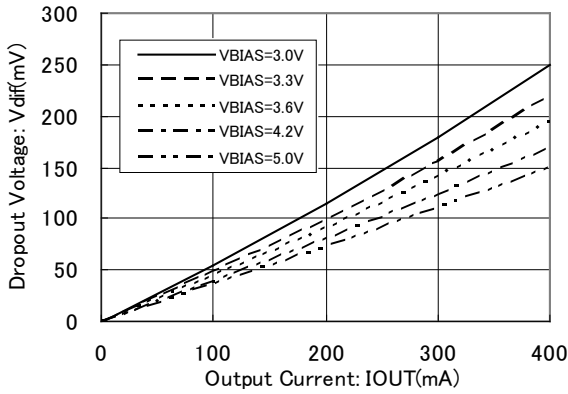


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(4) Dropout Voltage vs. Output Current

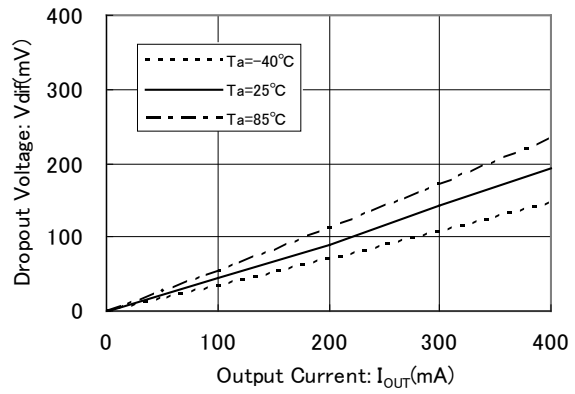
XC6601B121MR

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $T_a=25^\circ\text{C}$



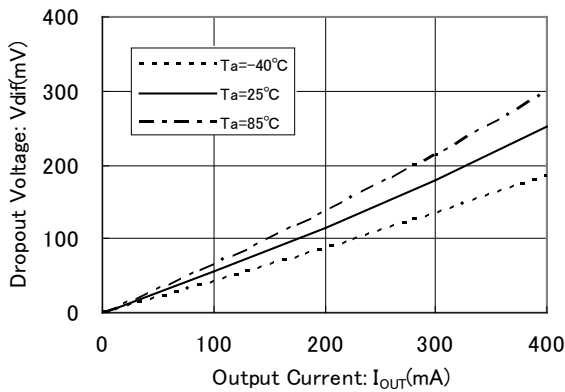
XC6601B121MR ($V_{gs}^{(*1)}=2.4\text{V}$)

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=3.6\text{V}$



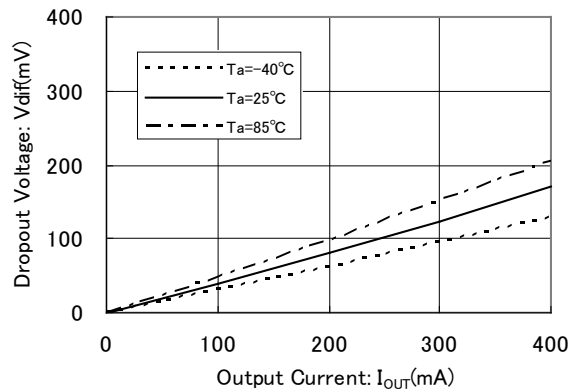
XC6601B121MR ($V_{gs}^{(*1)}=1.8\text{V}$)

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=3.0\text{V}$



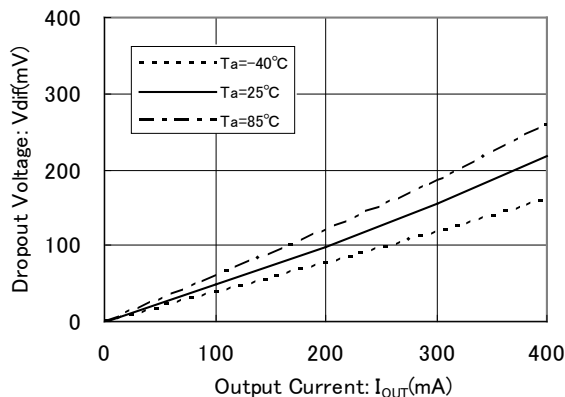
XC6601B121MR ($V_{gs}^{(*1)}=3.0\text{V}$)

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=4.2\text{V}$



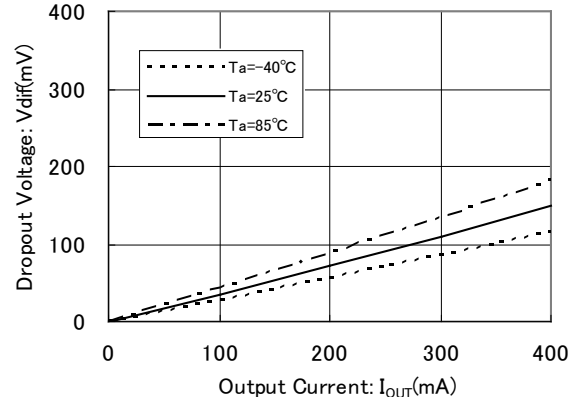
XC6601B121MR ($V_{gs}^{(*1)}=2.1\text{V}$)

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=3.3\text{V}$



XC6601B121MR ($V_{gs}^{(*1)}=3.8\text{V}$)

$C_{IN}=C_{BIAS}=1.0\ \mu\text{F(ceramic)}$, $C_L=4.7\ \mu\text{F(ceramic)}$
 $V_{BIAS}=5.0\text{V}$

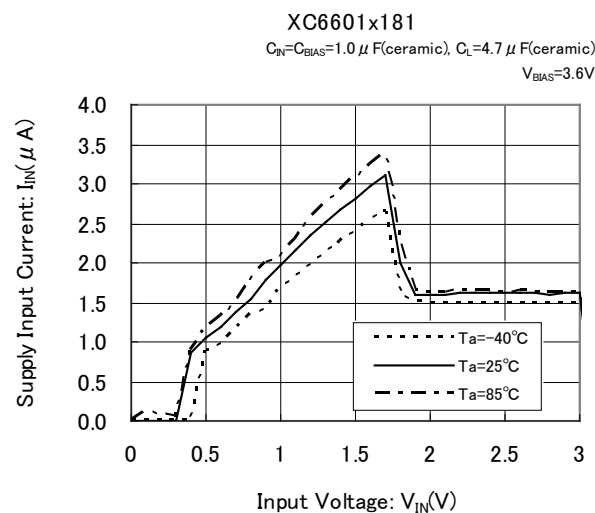
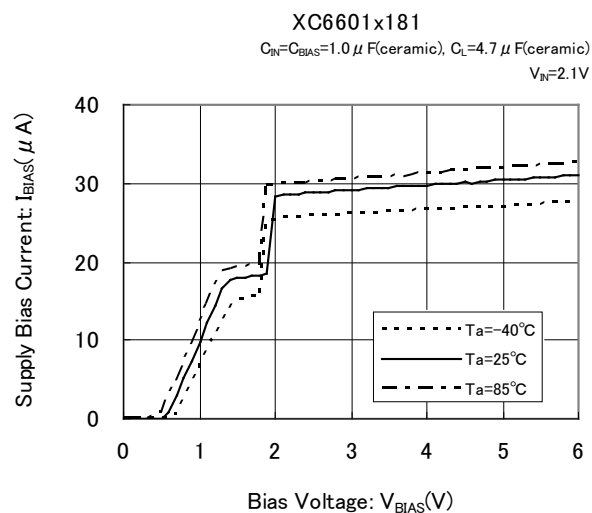
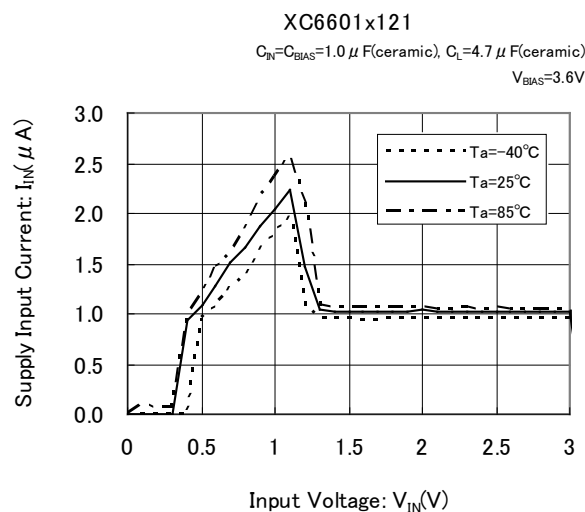
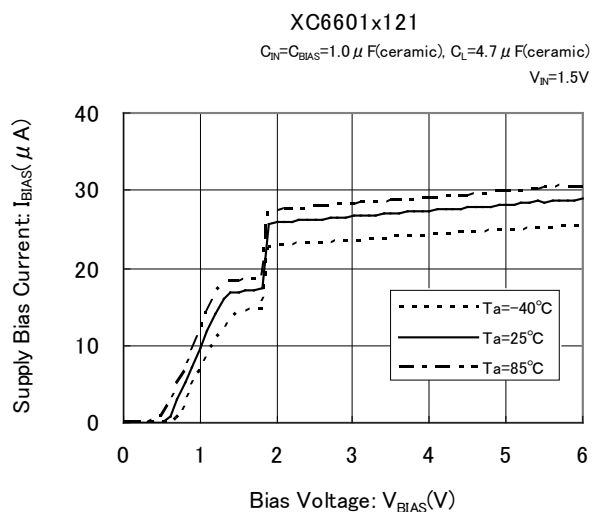
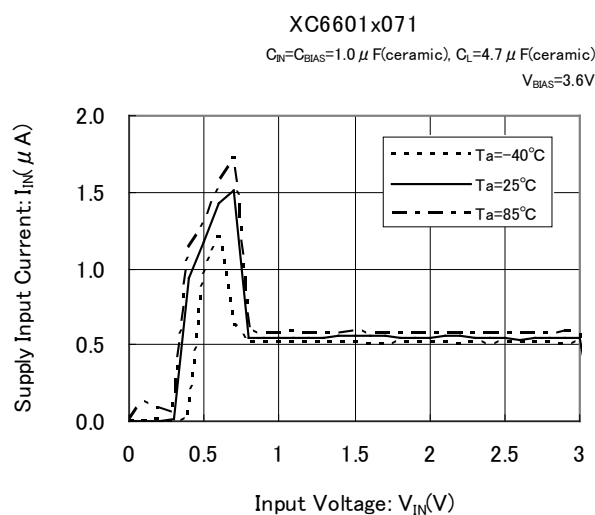
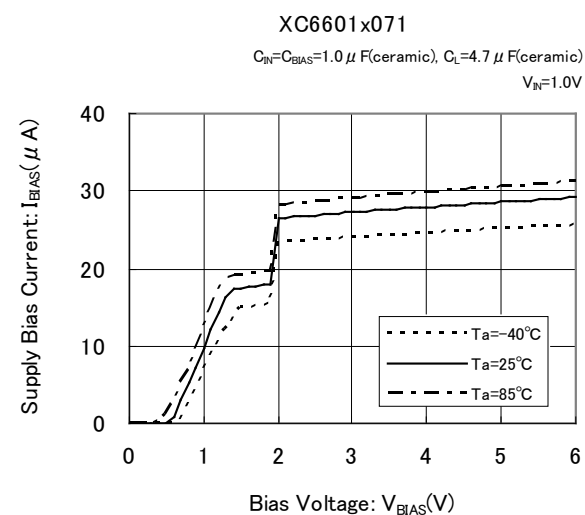


*1): V_{gs} is a Gate-Source voltage of the driver transistor that is defined as the value of $V_{BIAS} - V_{OUT}$ (T).
 A value of the dropout voltage is determined by the value of the V_{gs} .

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

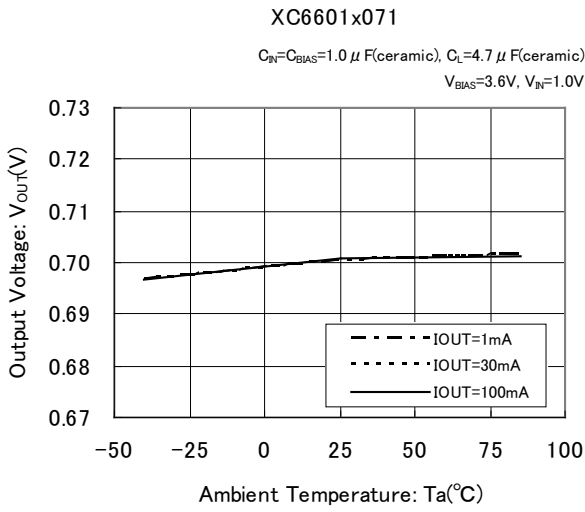
(5) Supply Bias Current vs. Bias Voltage

(6) Supply Input Current vs. Input Voltage

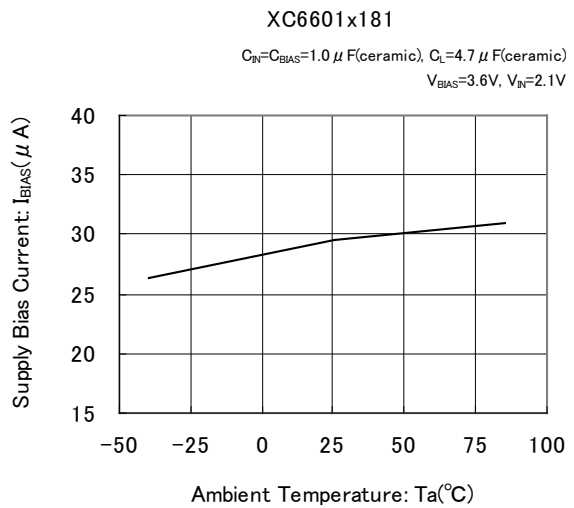
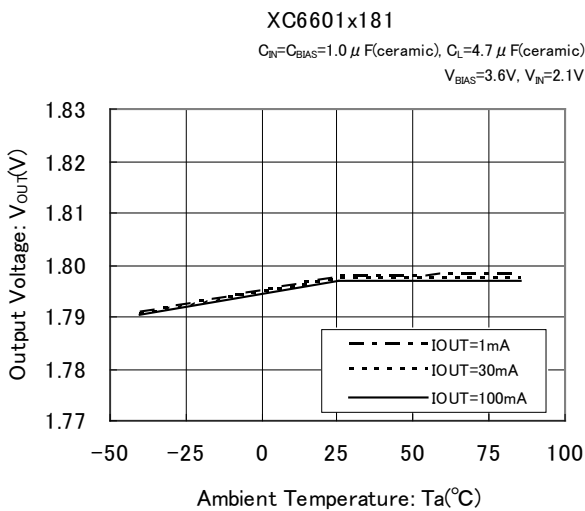
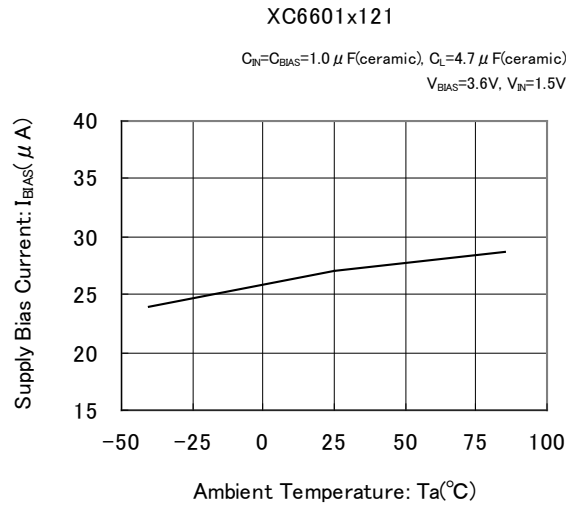
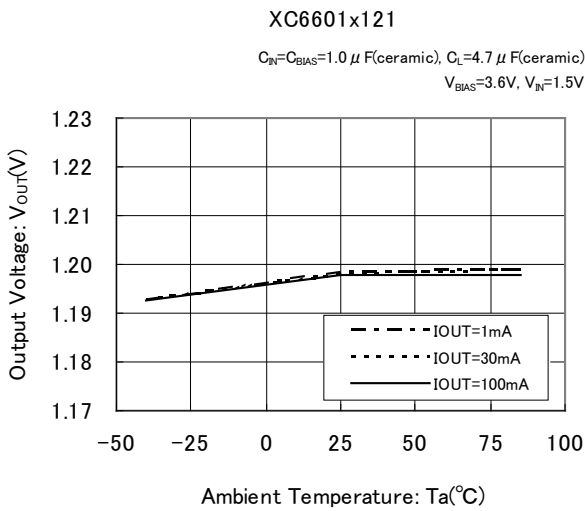
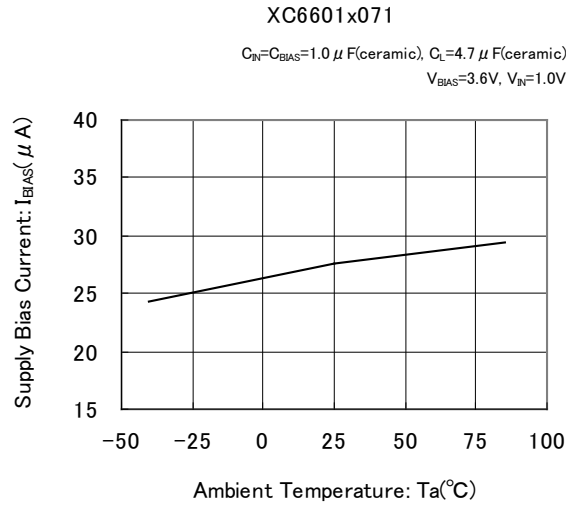


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(7) Output Voltage vs. Ambient Temperature

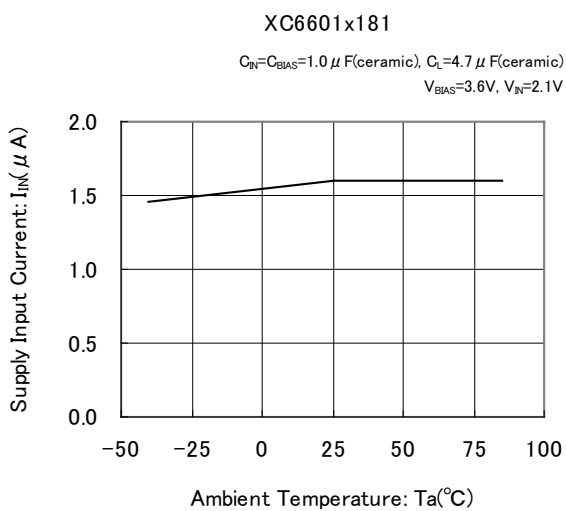
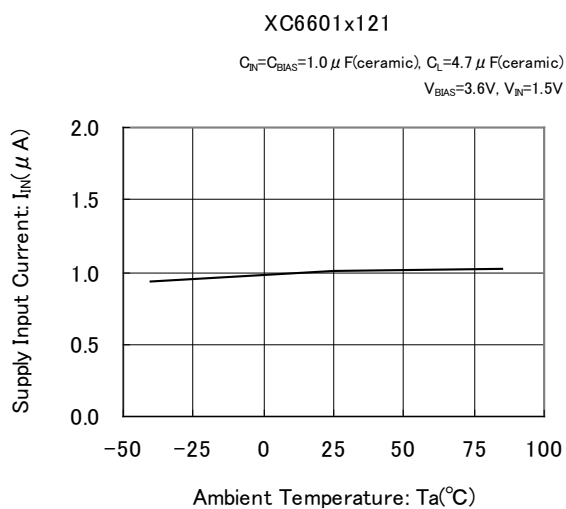
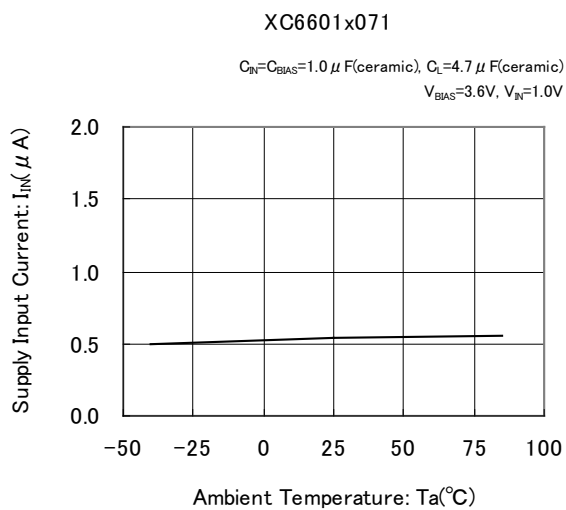


(8) Supply Bias Current vs. Ambient Temperature



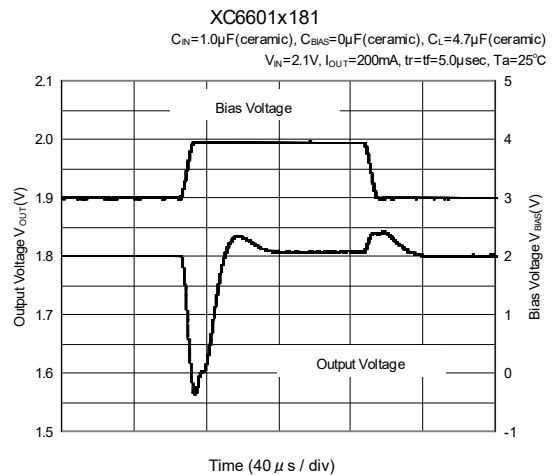
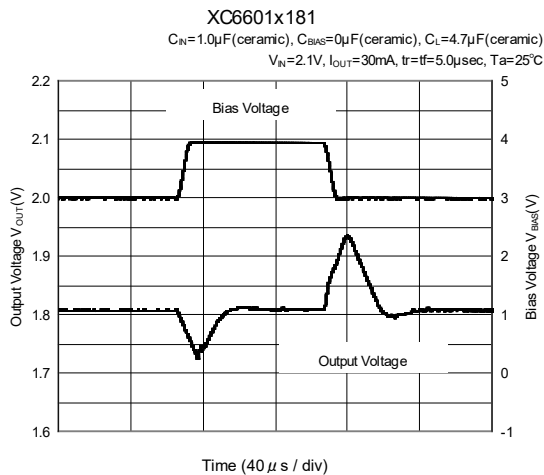
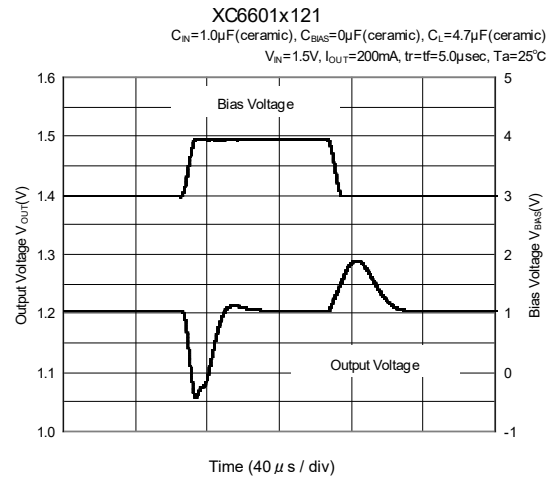
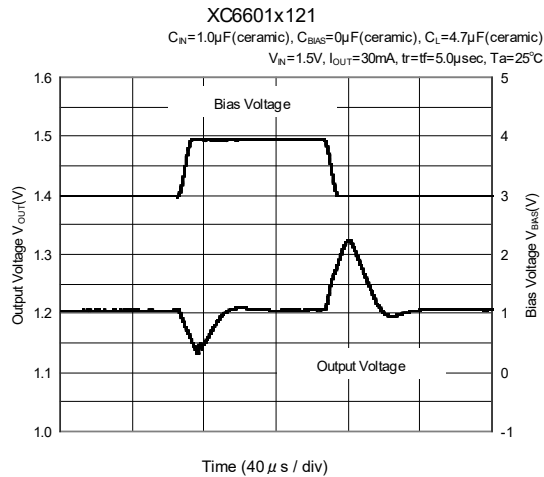
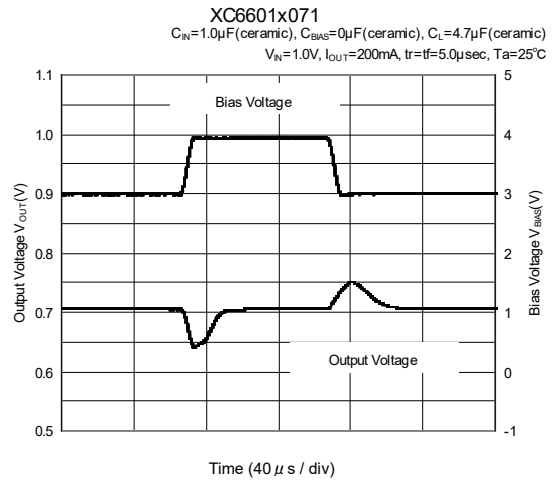
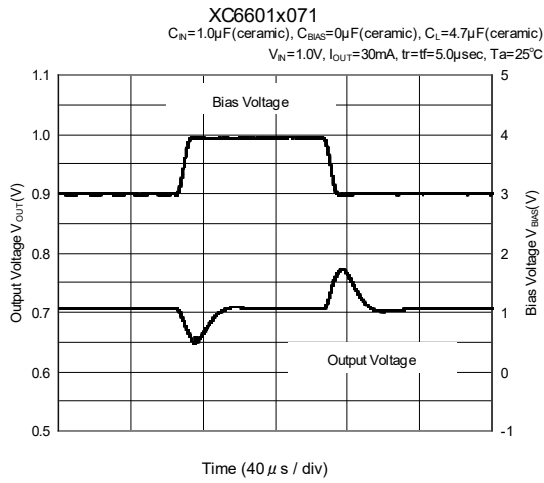
■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(9) Supply Input Current vs. Ambient Temperature



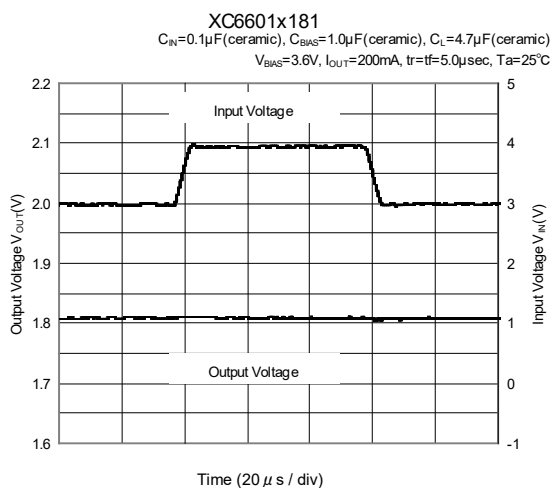
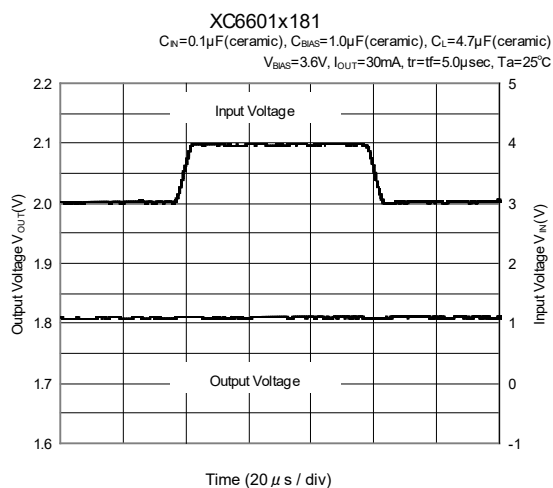
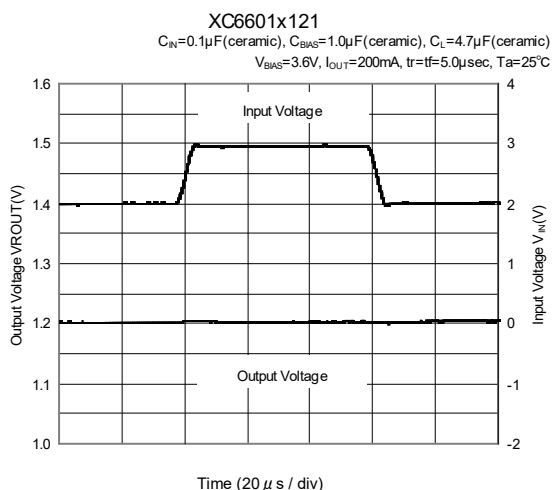
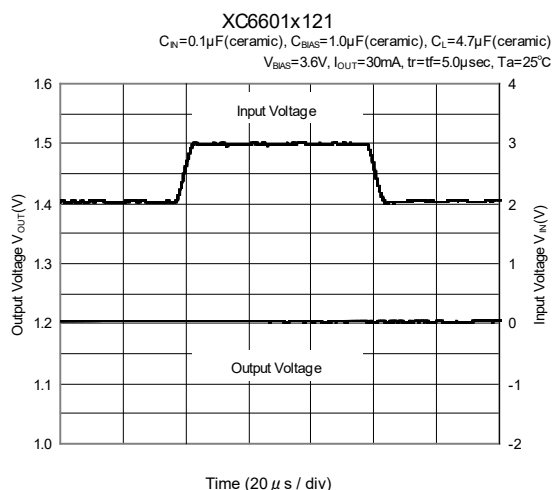
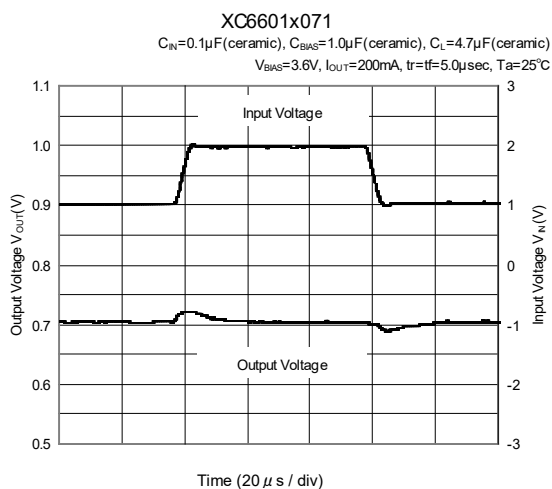
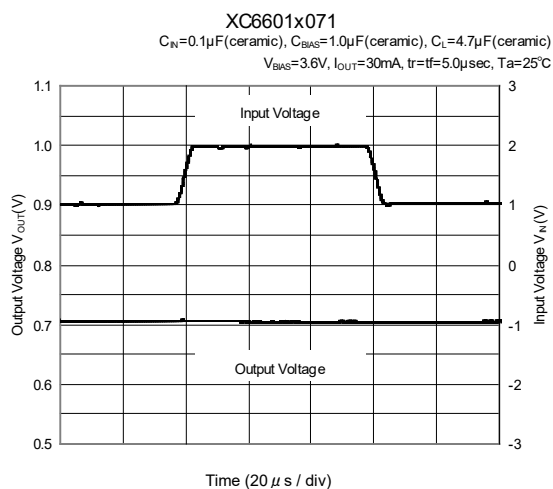
TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(10) Bias Transient Response



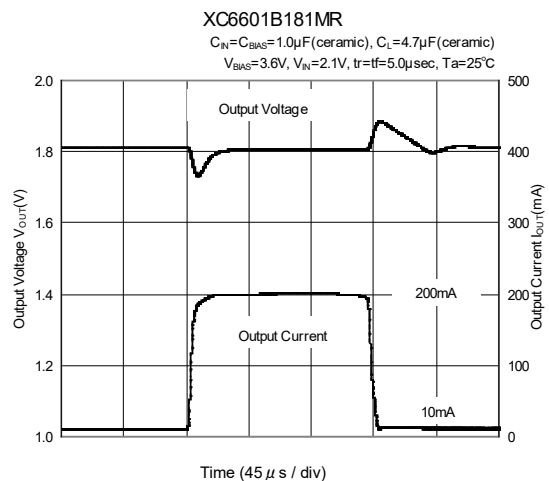
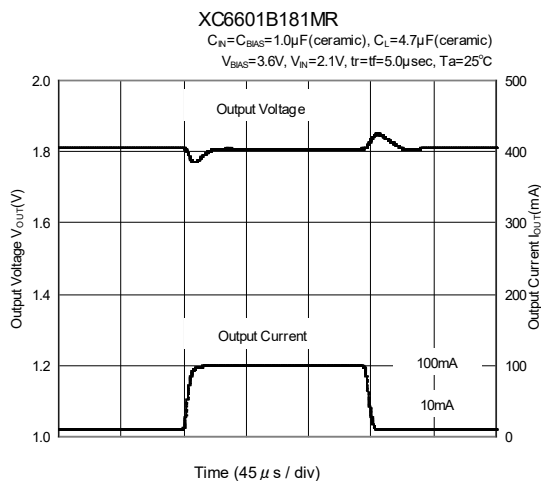
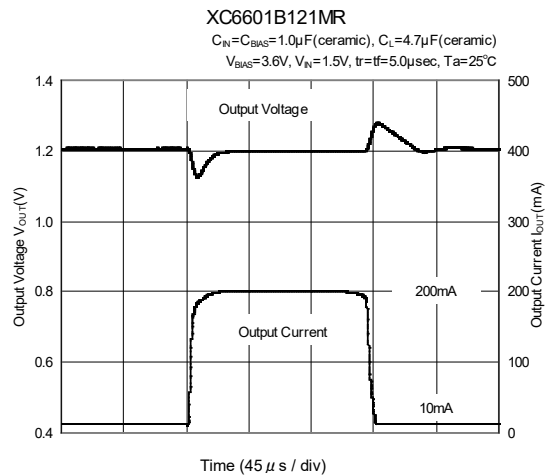
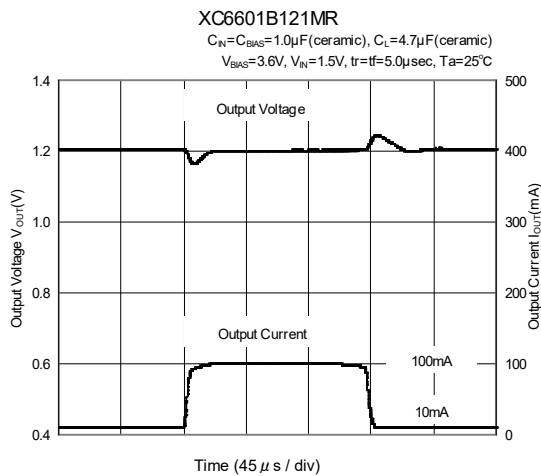
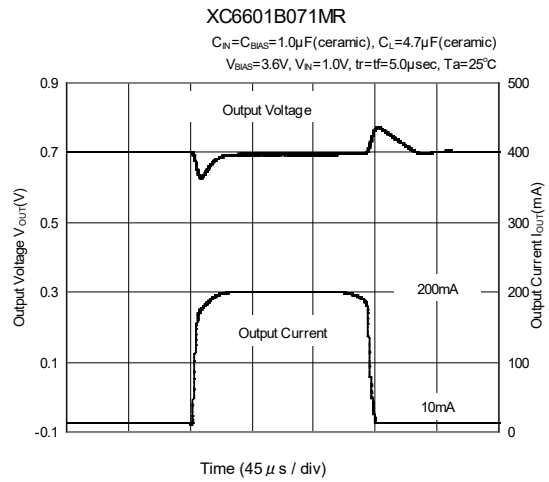
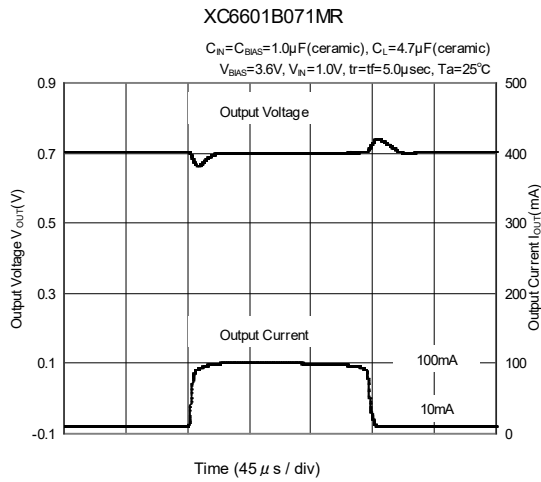
■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(11) Input Transient Response



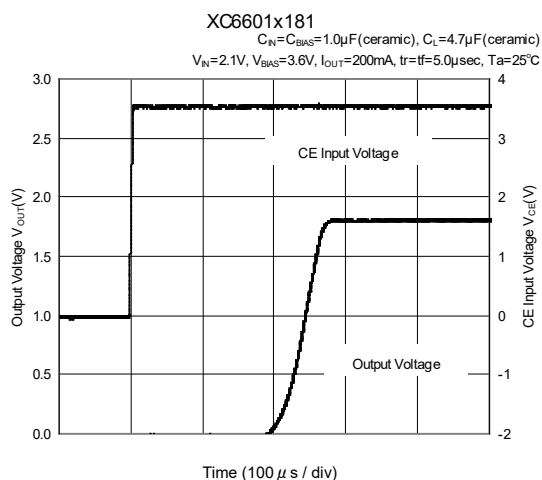
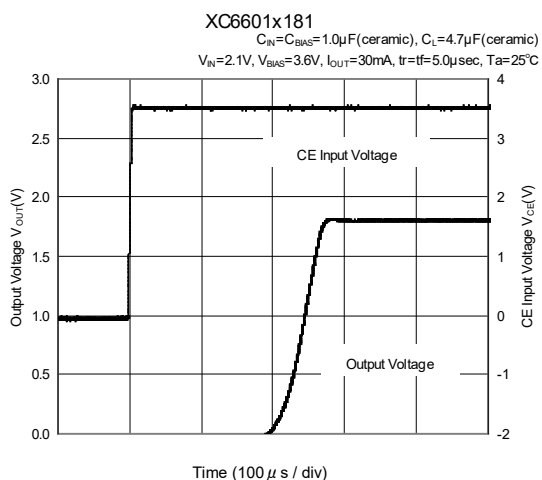
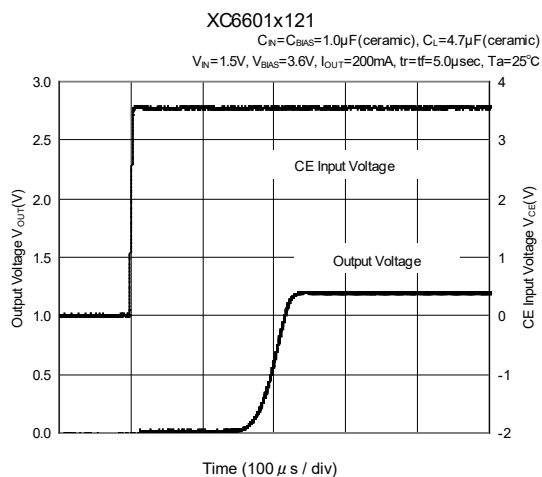
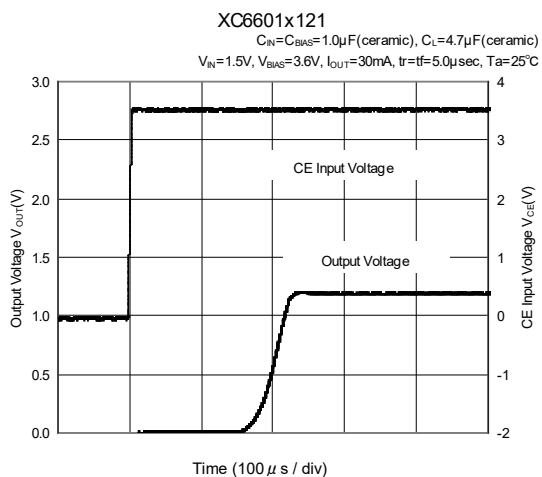
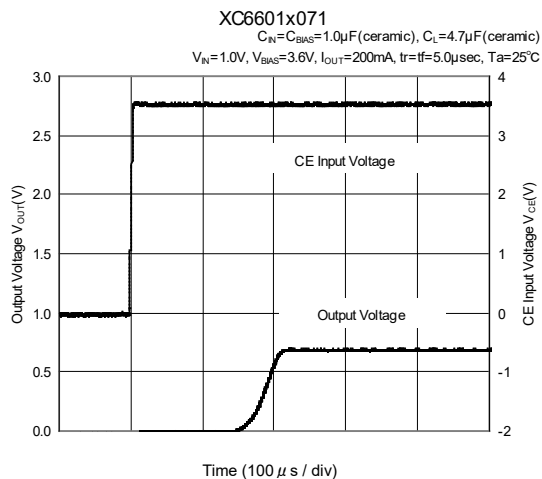
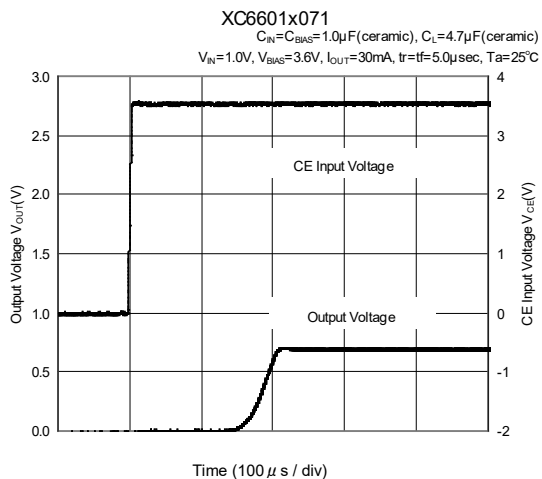
TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(12) Load Transient Response



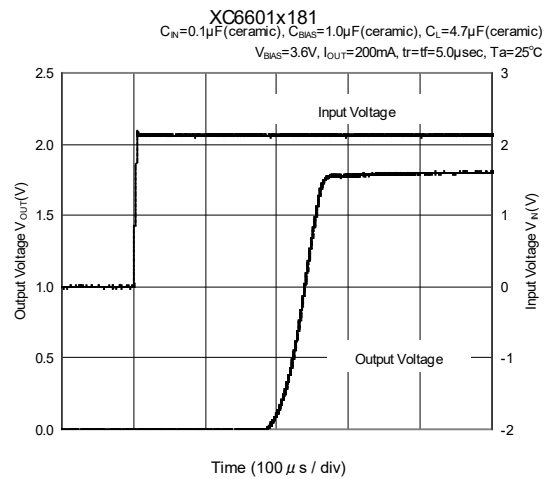
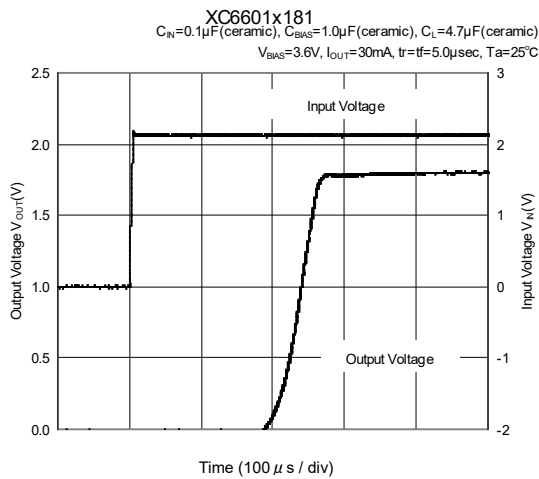
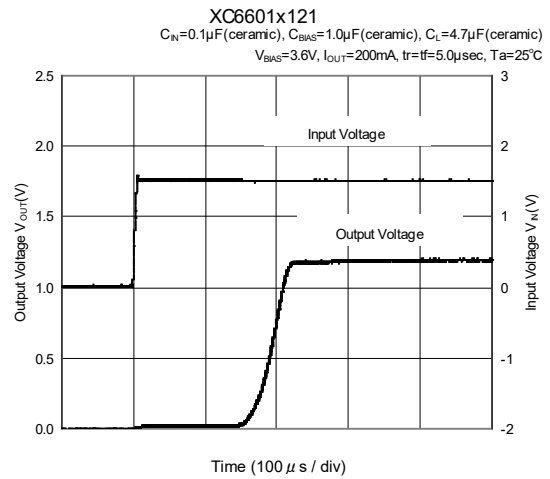
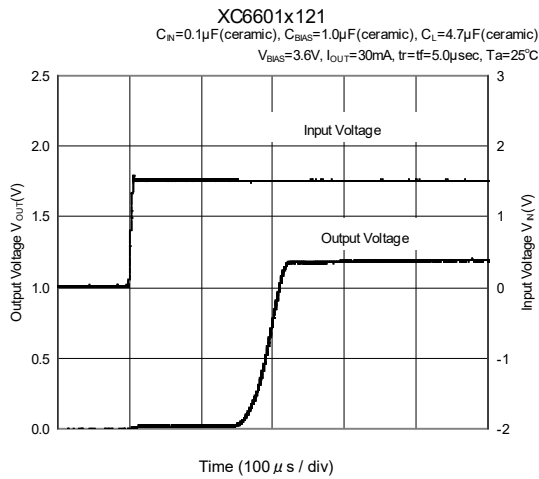
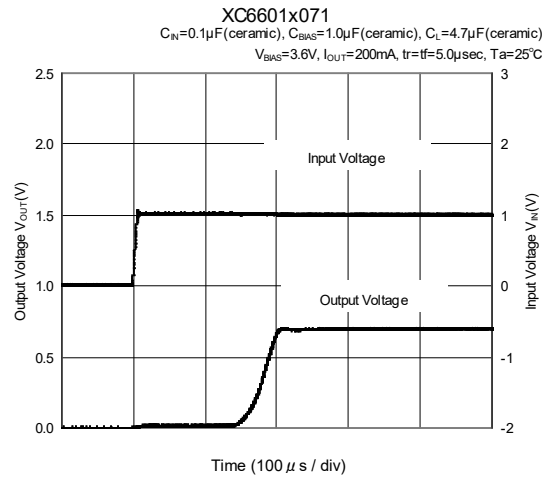
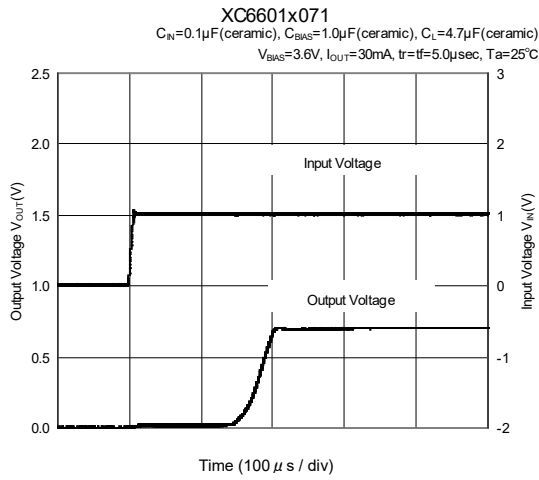
■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(13) CE Rising Response Time



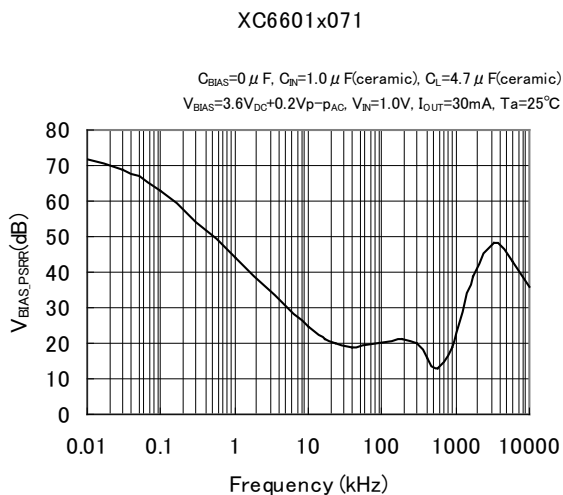
TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(14) V_{IN} Rising Response Time

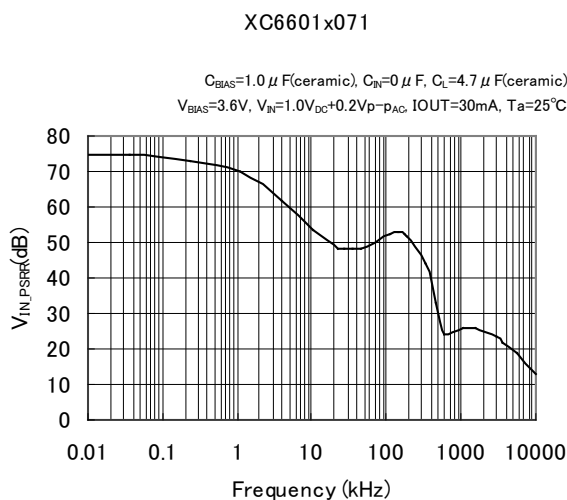


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

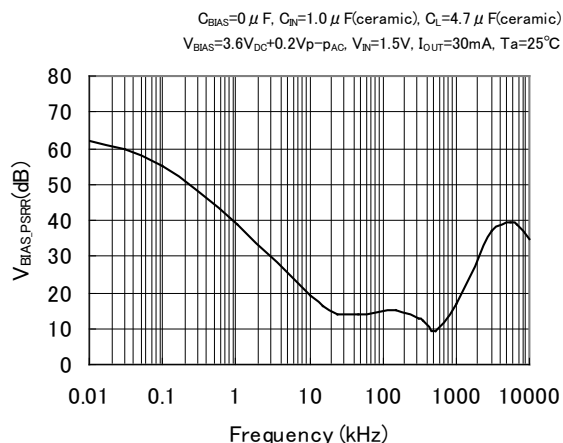
(15) Bias Voltage Ripple Rejection Rate



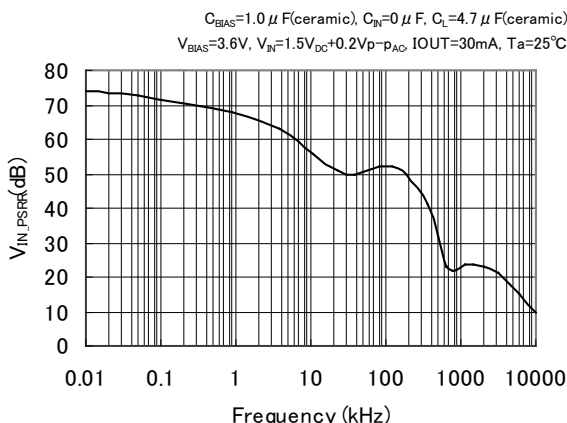
(16) Input Voltage Ripple Rejection Rate



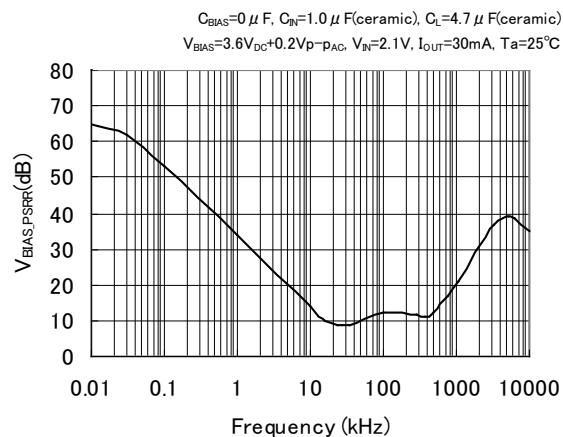
XC6601x121



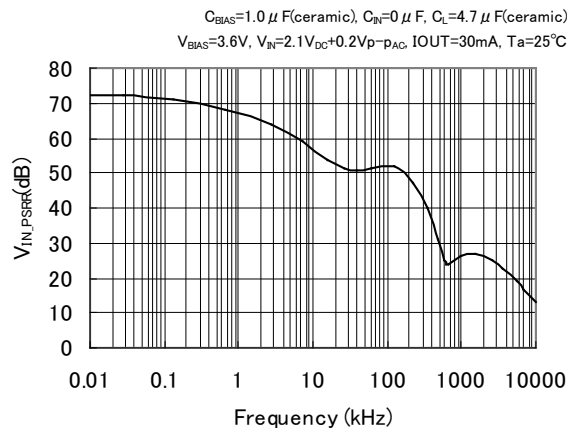
XC6601x121



XC6601x181



XC6601x181



■ PACKAGING INFORMATION

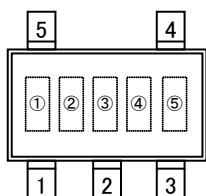
For the latest package information go to, www.torexsemi.com/technical-support/packages

| PACKAGE | OUTLINE / LAND PATTERN | THERMAL CHARACTERISTICS |
|----------|------------------------------|--|
| SOT-25 | SOT-25 PKG | SOT-25 Power Dissipation |
| SOT-89-5 | SOT-89-5 PKG | SOT-89-5 Power Dissipation |
| USP-6C | USP-6C PKG | USP-6C Power Dissipation |

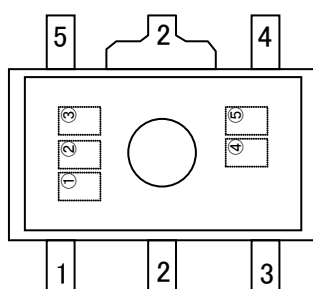
MARKING RULE

● SOT25, 89-5, USP6C

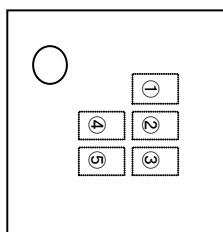
SOT25



SOT89-5



USP6C



① represents product series

| MARK | PRODUCT SERIES |
|------|----------------|
| 9 | XC6601***** |

② represents type of regulators

| MARK | OUTPUT VOLTAGE RANGE |
|------|----------------------|
| A | XC6601A***** |
| B | XC6601B***** |

③ represents output voltage

| MARK | OUTPUT VOLTAGE (V) | MARK | OUTPUT VOLTAGE (V) |
|------|--------------------|------|--------------------|
| 0 | 0.7 | F | 1.45 |
| 1 | 0.75 | H | 1.5 |
| 2 | 0.8 | K | 1.55 |
| 3 | 0.85 | L | 1.6 |
| 4 | 0.9 | M | 1.65 |
| 5 | 0.95 | N | 1.7 |
| 6 | 1.0 | P | 1.75 |
| 7 | 1.05 | R | 1.8 |
| 8 | 1.1 | S | - |
| 9 | 1.15 | T | - |
| A | 1.2 | U | - |
| B | 1.25 | V | - |
| C | 1.3 | X | - |
| D | 1.35 | Y | - |
| E | 1.4 | Z | - |

④,⑤ represents production lot number
 01~09, 0A~0Z, 11...9Z, A1~A9,
 AA...Z9, ZA~ZZ repeated
 (G, I, J, O, Q, W excluded)
 *No character inversion used.

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[MIC5512-1.2YMT-T5](#) [MIC5317-2.8YM5-T5](#) [SCD7912BTG](#) [NCP154MX180270TAG](#) [SCD33269T-5.0G](#) [NCV8170BMX330TCG](#)
[NCV8170AMX120TCG](#) [NCP706ABMX300TAG](#) [NCP153MX330180TCG](#) [NCP114BMX075TCG](#) [MC33269T-3.5G](#) [CAT6243-ADJCMT5T](#)
[TCR3DG33,LF](#) [AP2127N-1.0TRG1](#) [BD3021HFP-MTR](#) [TCR4DG35,LF](#) [LT1117CST-3.3](#) [TAR5S15U\(TE85L,F\)](#) [TAR5S18U\(TE85L,F\)](#)
[TCR3UG19A,LF](#) [TCR4DG105,LF](#) [NCV8170AMX360TCG](#) [MIC94310-NYMT-T5](#) [NCV4266-2CST33T3G](#) [NCV8186BMN175TAG](#)